THALES

Cinterion® PLSx3

Hardware Interface Description

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1 Introduction

This document¹ describes the hardware of the Cinterion[®] PLSx3 module. It helps you quickly retrieve interface specifications, electrical and mechanical details and information on the requirements to be considered for integrating further components.

Note: This Hardware Interface Description is a preliminary version and as such subject to change depending on further implementation and measurements.

1.1 Product Variants

This document applies to the following Thales module variants:

- Cinterion[®] PLS63-W-B Module
- Cinterion® PLS63-W-B Module
- Cinterion[®]PLS63-X-B Module
- Cinterion[®] PLS83-X-B Module

Note: The PLSx3 variants differ in the fact that PLS63 supports UE CAT 1 (DL 10Mbps, UL 5Mbps) whereas PLS83 supports UE CAT 4(DL 150Mbps, UL 50Mbps). Wherever necessary a note is made to differentiate between the product variants.

^{1.} The document is effective only if listed in the appropriate Release Notes as part of the technical documentation delivered with your Thales product.

1.2 Key Features at a Glance

Feature	Implementation				
General	General				
Frequency bands	PLSx3 integrates all the bands required to have a global coverage across the world (NORAM / LATAM / EMEA /APAC). Please refer to Section 1.2.1 for an overview of the frequency bands supported by each PLSx3 product variant.				
GSM class	Small MS				
Output power (according to release 99)	Class 4 (+33dBm ±2dB) for GSM850 Class 4 (+33dBm ±2dB) for GSM900 Class 1 (+30dBm ±2dB) for GSM1800 Class 1 (+30dBm ±2dB) for GSM1900 Class E2 (+27dBm ± 3dB) for GSM 850 8-PSK Class E2 (+27dBm ± 3dB) for GSM 900 8-PSK Class E2 (+26dBm +3 /-4dB) for GSM 1800 8-PSK Class E2 (+26dBm +3 /-4dB) for GSM 1900 8-PSK				
Output power (according to Release 99)	Class 3 (+24dBm +1/-3dB) for UMTS 850, WCDMA FDD BdXIX Class 3 (+24dBm +1/-3dB) for UMTS 850, WCDMA FDD BdVI Class 3 (+24dBm +1/-3dB) for UMTS 850, WCDMA FDD BdV Class 3 (+24dBm +1/-3dB) for UMTS 900, WCDMA FDD BdVIII Class 3 (+24dBm +1/-3dB) for UMTS 1700, WCDMA FDD BdIII Class 3 (+24dBm +1/-3dB) for UMTS 1900, WCDMA FDD BdII Class 3 (+24dBm +1/-3dB) for UMTS 2100, WCDMA FDD BdIV Class 3 (+24dBm +1/-3dB) for UMTS 2100, WCDMA FDD BdI				
Output power (according to Release 8)	Class 3 (+23dBm ±2dB) for LTE 600, LTE FDD Bd71 Class 3 (+23dBm ±2dB) for LTE 700, LTE FDD Bd12 <mfbi bd17=""> Class 3 (+23dBm ±2dB) for LTE 700, LTE FDD Bd13 Class 3 (+23dBm ±2dB) for LTE 700, LTE FDD Bd14 Class 3 (+23dBm ±2dB) for LTE 700, LTE FDD Bd28 Class 3 (+23dBm ±2dB) for LTE 850, LTE FDD Bd26 Class 3 (+23dBm ±2dB) for LTE 850, LTE FDD Bd18 Class 3 (+23dBm ±2dB) for LTE 850, LTE FDD Bd19 Class 3 (+23dBm ±2dB) for LTE 850, LTE FDD Bd20 Class 3 (+23dBm ±2dB) for LTE 850, LTE FDD Bd5 Class 3 (+23dBm ±2dB) for LTE 850, LTE FDD Bd5 Class 3 (+23dBm ±2dB) for LTE 850, LTE FDD Bd8 Class 3 (+23dBm ±2dB) for LTE 1800, LTE FDD Bd3 Class 3 (+23dBm ±2dB) for LTE 1900, LTE FDD Bd2 Class 3 (+23dBm ±2dB) for LTE 1900, LTE FDD Bd2 Class 3 (+23dBm ±2dB) for LTE 2100, LTE FDD Bd4 Class 3 (+23dBm ±2dB) for LTE 2100, LTE FDD Bd4 Class 3 (+23dBm ±2dB) for LTE 2100, LTE FDD Bd7 Class 3 (+23dBm ±2dB) for LTE 2500, LTE TDD Bd40 Class 3 (+23dBm ±2dB) for LTE 2500, LTE TDD Bd41 Class 3 (+23dBm ±2dB) for LTE 2500, LTE TDD Bd41 Class 3 (+23dBm ±2dB) for LTE 2500, LTE TDD Bd41 Class 3 (+23dBm ±2dB) for LTE 2500, LTE TDD Bd41 Class 3 (+23dBm ±2dB) for LTE 2500, LTE TDD Bd41 Class 3 (+23dBm ±2dB) for LTE 2500, LTE TDD Bd38</mfbi>				
Power supply (see Section 2.1.2, and Section 3.4)	Normal operation: 3.0V ≤ V _{BATT+} ≤ 4.5V Typ value is 3.8V				
Operating temperature (board temperature) (see Section 3.5)	Normal operation: -30°C to +85°C Extended operation: -40°C to -30°C, +85°C to +95°C;				

Feature	Implementation
Physical (see Section 4.1)	Dimensions: 33mm x 29mm x 2.5mm Weight: approx. 4.8g
RoHS (see Section 5.1)	All hardware components fully compliant with EU RoHS Directive
LTE features	
3GPP Release 10	UE CAT 1 for PLS63 (DL 10Mbps, UL 5Mbps) UE CAT 4 for PLS83 (DL 150Mbps, UL 50Mbps)
HSPA feature	
3GPP Release 7	UE CAT. 8, 6 for PLS63 HSDPA – DL 7.2Mbps HSUPA – UL 5.7Mbps UE CAT. 14, 6 for PLS83 HSPA+ – DL 21Mbps HSUPA – UL 5.7Mbps Compressed mode (CM) supported according to 3GPP TS25.212
UMTS features	
3GPP Release 4	PS data rate – 384 kbps DL / 384 kbps UL
GSM/GPRS/EGPRS feat	ures
Data transfer	 GPRS: Multislot Class 12 Mobile Station Class B Coding Scheme 1 – 4 EGPRS: Multislot Class 12 EDGE E2 power class for 8 PSK Downlink coding schemes – CS 1-4, MCS 1-9 Uplink coding schemes – CS 1-4, MCS 1-9 SRB loopback and test mode B 8-bit, 11-bit RACH 1 phase/2 phase access procedures Link adaptation and IR NACC, extended UL TBF Mobile Station Class B
SMS	Point-to-point MT and MO Cell broadcast Text and PDU mode Storage: SIM card plus SMS locations in mobile equipment
GNSS Features	
Protocol	NMEA
Modes (see Section 2.3)	Standalone GNSS (GPS, GLONASS, Beidou, Galileo, QZSS)
General	Automatic power saving modes. DC feed bridge and control of power supply for active antenna
Software	

Feature	Implementation
AT commands	Hayes 3GPP TS 27.007, TS 27.005, Thales
SIM Application Toolkit	Default (Network) bearer support for BIP
Firmware update	Generic update from host application over USB modem
Interfaces	
Module interface	Surface mount device with solderable connection pads (SMT application interface). Land grid array (LGA) technology ensures high solder joint reliability and allows the use of an optional module mounting socket.
	For more information on how to integrate SMT modules see also [4]. This application note comprises chapters on module mounting and application layout issues as well as on additional SMT application development equipment.
USB (see Section 2.1.3)	USB 2.0 High Speed (480Mbit/s) device interface. Full Speed (12Mbit/s) compliant.
2 serial interfaces (see Section 2.1.4, and Section 2.1.5)	 ASC0 (in parts shared with GPIO lines): 8-wire modem interface with status and control lines, unbalanced, asynchronous Fixed baud rates: 300bps to 921,600bps and 3M Supports RTS0/CTS0 hardware flow control. ASC1 (shared with GPIO lines): 4-wire, unbalanced asynchronous interface Fixed baud rates: 300bps to 921,600bps Supports RTS1/CTS1 hardware flow control
2 UICC interfaces (switchable) (see Section 2.1.6)	Supported chip cards: UICC/SIM/USIM 3V, 1.8V
GPIO interface (see Section 2.1.7)	22 GPIO lines comprising: 12 lines shared with ASC0, ASC1 lines, with network status indication, fast shutdown, SIM switch and Antenna Switch 10GPIO lines not shared
RING0	Support RING0 to wake up host from power saving state.
Antenna interface pads (see Section 2.1)	$50\Omega.$ UMTS/GSM/LTE main antenna, UMTS/LTE Rx Diversity antenna, GNSS antenna.
ADC inputs (see Section 2.1.8)	Analog-to-Digital Converter with unbalanced analog inputs, for example, for the (external) antenna diagnosis
Power on/off, Reset	
Power on/off	Switch on by hardware signal IGT Switch off by AT command Switch off by hardware signal FST_SHDN instead of AT command Automatic switch off in case of critical temperature or voltage conditions
Reset	Orderly reset by AT command Reset by emergency reset signal EMERG_RST.
Special features	
Real time clock	Timer functions via AT commands.
Evaluation kit	
LGA DevKit	LGA DevKit designed to test Thales LGA modules.

Feature	Implementation
Evaluation module	PLSx3 module soldered onto a dedicated PCB that can be connected to an adapter in order to be mounted onto the DSB75 or DSB mini.
DSB-mini	DSB-mini Development Support Board designed to test and type approve. It is the cost optimized development board alternative to DSB75.
DSB75	DSB75 Development Support Board designed to test and type approve Thales modules and provide a sample configuration for application engineering. A special adapter is required to connect the PLSx3 evaluation module to the DSB75.

1.2.1 Supported Frequency Bands

The following table lists the supported frequency bands for each of the PLSx3 product variants mentioned in Section 1.1.

Table 1: Supported frequency bands for each PLSx3 variant

Band	PLSx3-W	PLSx3-X		
GSM/GPRS/EDGE				
850MHz	Х			
900MHz	Х			
1800MHz	Х			
1900MHz	Х			
WCDMA	1			
Bd.1 (2100MHz)	Х			
Bd.2 (1900MHz)	Х	X		
Bd.3 (1800MHz)	Х			
Bd.4 (2100MHz)	Х	Х		
Bd.5 (850MHz)	Х	X		
Bd.6 (850MHz)	Х			
Bd.8 (900MHz)	Х			
Bd.19 (850MHz)	Х			
LTE-FDD	1			
Bd.1 (2100MHz)	Х			
Bd.2 (1900MHz)	Х	Х		
Bd.3 (1800MHz)	Х			
Bd.4 (2100MHz)	X	X		
Bd.5 (850MHz)	Х	Х		
Bd.7 (2600MHz)	Х			
Bd.8 (900MHz)	Х			
Bd.12 (700MHz)	Х	X		
Bd.13 (700MHz) ¹	Х	Х		
Bd.14(700MHz)		Х		
Bd.17 (700 MHz)				
Bd.18 (850MHz)	Х			
Bd.19 (850MHz)	Х			
Bd.20 (800MHz)	Х			
Bd.25(1900MHz)		х		
Bd.26 (850MHz)	Х	х		
Bd.28 (700MHz)	Х			

Table 1: Supported frequency bands for each PLSx3 variant

Band	PLSx3-W	PLSx3-X			
Bd.66(2100MHz)	Х	Х			
Bd.71(600MHz)		Х			
LTE-TDD					
Bd.38 (2600MHz)	Х				
Bd.40 (2300MHz)	Х				
Bd.41 (2500MHz)	Х				

^{1.} For -W variant module, a sensitivity issue will occur in GNSS when transmitting in band 13, to avoid this issue, it is suggested to use -X variant module.

^{2.} For Band 41 (LTE-TDD), the frequency range are partially supported (2535MHz...2675MHz).

1.3 PLSx3 System Overview

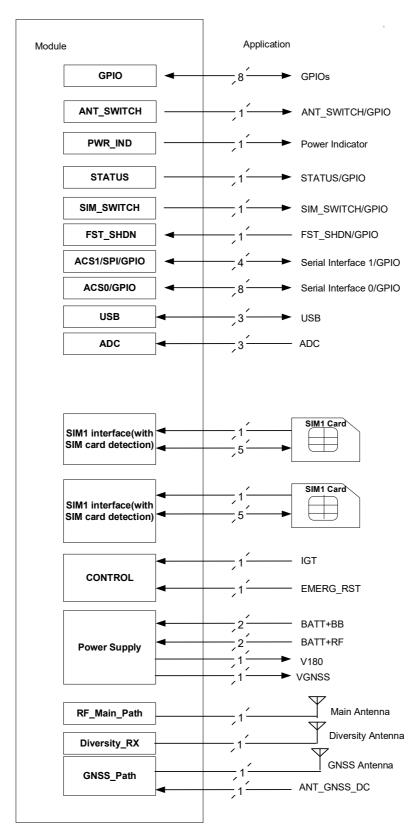


Figure 1: PLSx3 system overview

1.4 Circuit Concept

Figure 2 shows block diagrams of the PLSx3 module and illustrate the major functional components:

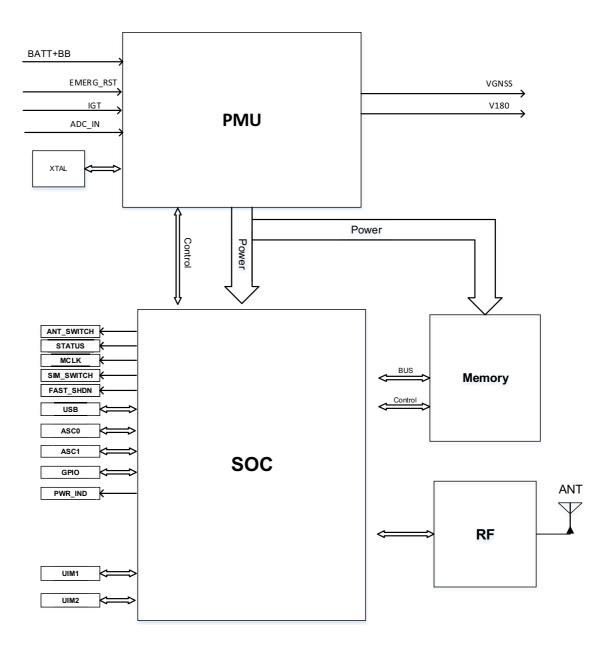


Figure 2: PLSx3 block diagram

2 Interface Characteristics

PLSx3 is equipped with an SMT application interface that connects to the external application. The SMT application interface incorporates the various application interfaces as well as the RF antenna interface.

2.1 Application Interface

2.1.1 Pad Assignment

The SMT application interface on the PLSx3 provides land grid array pads to integrate the module into external applications. Table 2 lists the pad assignment. Figure 3 shows the pin mapping on the LGA footprint.

Please note that a number of connecting pads are marked as reserved for future use (rfu) and further qualified as either (dnu), (GND) or (nc):

- Pads marked "rfu" and qualified as "dnu" (do not use) shall be soldered but electrically not connected.
- Pads marked "rfu" and qualified as "nc" (not connected) are internally not connected with PLSx3 modules, but shall be soldered.

Thales strongly recommends to solder all connecting pads for mechanical stability and heat dissipation.

Table 2: Overview: Pad assignments

Pad No.	Signal Name	Pad No.	Signal Name	Pad No.	Signal Name
A4	rfu (no)	E2	GND	L2	GND
A5	rfu (nc)	E3	GND	L3	GND
A6	GND	E4	GND	L4	GND
A7	GND	E5	GND	L5	rfu (nc)
A8	GND	E12	CCIO2	L6	CCVCC2
A9	GND	E13	CCRST2	L7	rfu (dnu)
A10	GND	E14	rfu (nc)	L8	rfu (nc)
A11	GND	E15	rfu (dnu)	L9	rfu (nc)
A12	ANT DRX	E16	rfu (dnu)	L10	rfu (nc)
A13	GND	F1	GND	L11	SIM SWITCH/GPIO26
В3	rfu (nc)	F2	GND	L12	rfu (nc)
B4	GND	F3	GND	L13	rfu (dnu)
B5	GND	F4	GND	L14	CCRST1
B6	GND	F13	GND	L15	CCCLK1
B7	GND	F14	rfu (dnu)	L16	IGT
B8	GND	F15	rfu (dnu)	M2	GND
В9	GND	F16	GPÌO25	М3	GND
B10	GND	G1	GND	M4	PWR_IND
B11	GND	G2	GND	M5	V180
B12	GND	G3	GND	M6	GND
B13	GND	G4	GND	M7	GPIO21
B14	GPIO5/STATUS	G13	rfu (dnu)	M8	rfu (dnu)
C2	GND	G14	GPIO7	M9	rfu (dnu)
C3	GND	G15	GPIO8	M10	GPIO20
C4	GND	G16	GPIO11	M11	ADC3_IN
C5	GND	H1	GND	M12	ADC2_IN
C6	GND	H2	GND	M13	ADC1_IN
C7	GND	H3	GND	M14	CCIN1
C8 C9	GND GND	H4	GND	M15	rfu (nc)
C10	GND	H13 H14	rfu (dnu) GPIO4/FST_SHDN	N3 N4	BATT+ _{RF} BATT+ _{RF}
C10	GND	H15	GPI04/F31_3HDIN	N5	VUSB_IN
C12	rfu (nc)	H16	GPIO6	N6	GPIO19/CTS1
C13	rfu (dnu)	J1	GND	N7	GPIO18/RTS1
C14	rfu (dnu)	J2	GND	N8	CTS0
C15	GND	J3	GND	N9	DCD0/GPIO2
D1	GND	J4	GND	N10	RTS0
D2	GND	J13	GND	N11	GND
D3	GND	J14	GPIO15	N12	rfu (dnu)
D4	GND	J15	GPIO14	N13	BATT+ _{BB}
D5	ANT GNSS DC	J16	GPIO13/ANT SWITCH	N14	EMERG RST
D6	GND	K1	ANT_MAIN	P4	USB DP
D7	GND	K2	GND	P5	USB_DN
D8	GND	K3	GND	P6	GPIO16/RXD1
D9	GND	K4	GND	P7	GPIO17/TXD1
D10	GND	K5	GND	P8	DTR0/GPIO1
D11	GND	K12	rfu (nc)	P9	DSR0/GPIO3
D12	CCIN2	K13	rfu (dnu)	P10	RING0/GPIO24
D13	rfu (nc)	K14	CCIO1	P11	RXD0
D14	CCCLK2	K15	CCVCC1	P12	TXD0
D15	rfu (dnu)	K16	VGNSS	P13	BATT+ _{BB}
D16	rfu (dnu)	L1	GND		
E1	ANT_GNSS				

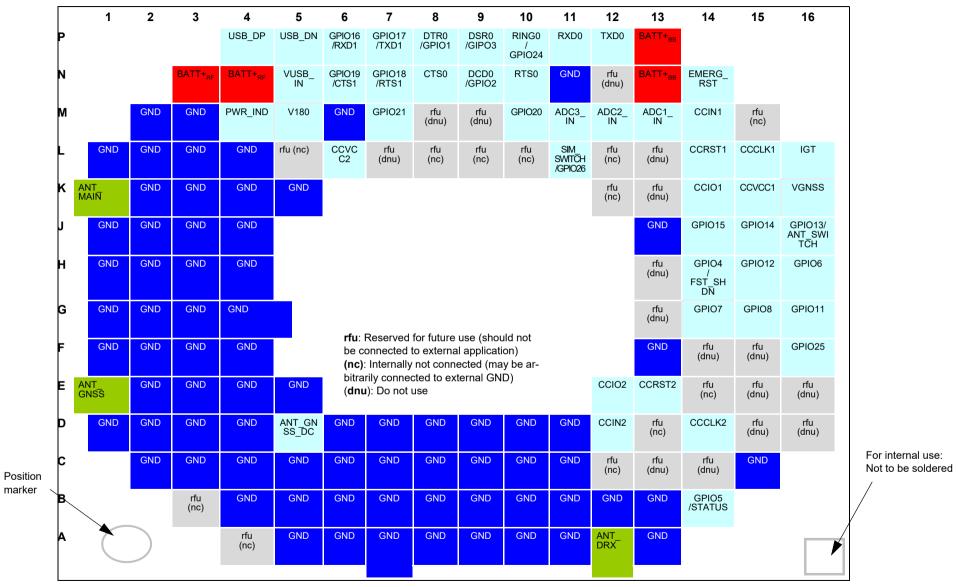


Figure 3: PLSx3 bottom view: Pad assignments

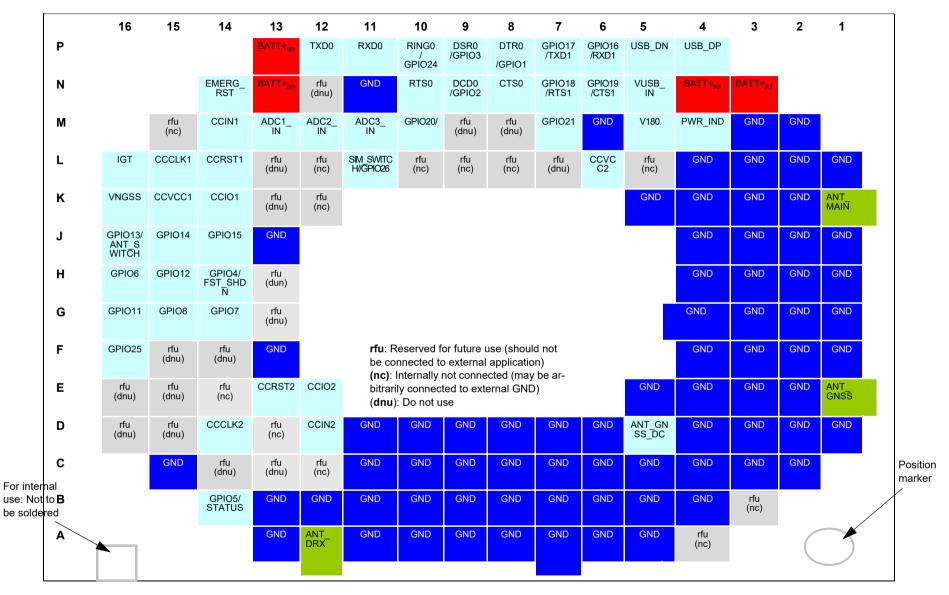


Figure 3: PLSx3 top view: Pad assignments

2.1.2 Signal Properties

Table 3: Signal properties (Sheet 1 of 5)

Function	Signal name	Ю	Signal form and level	Comment
Power supply	BATT+ _{BB} BATT+ _{RF}	I	GSM activated: V _I max = 4.5V V _I norm = 3.8V V _I min = 3.0V Imax= see Table 16	Lines of BATT+ and GND must be connected in parallel for supply purposes because higher peak currents may occur.
			n Tx = n x 577µs peak current every 4.616ms	Minimum voltage must not fall below 3.0V including drop, ripple, spikes and not rise above 4.5V.
			WCDMA activated: V _I max = 4.5V V _I norm = 3.8V V _I min = 3.0V during Transmit active. Imax = see Table 17 LTE activated: V _I max = 4.5V V _I norm = 3.8V V _I min = 3.0V during Transmit active. Imax = see Table 18	Note: The module's normal voltage range for operation lies between 3.0V and 4.5V. For USB operation, 3.0V-4.5V is also recommended.
External supply voltage	V180	0	Normal operation: V _O norm = 1.80V ±2% I _O max = 10mA	V180 should be used to supply level shifters at the interfaces.
			SLEEP mode Operation: V _O Sleep = 1.80V ±4% I _O max = 10mA Clmax = 100nF	Note: V180 is not back powering protected. Wrong usage may back power the module which is forbidden.
				If unused keep line open.
	VGNSS	0	CLmax=2.2 μ V _{O=} 3V±2%@I _O =-10mA I _O max = 10mA	Available when GNSS antenna DC power is enabled.
Supply voltage for active GNSS antenna	ANT_GNS- S_DC	I	V _I max_6V The input current has to be limited to 50mA(antenna short circuit protection)	If unused connect to GND

Table 3: Signal properties (Sheet 2 of 5)

Function	Signal name	Ю	Signal form and level	Comment
Ignition	IGT	I	Do not add any voltage on it. There is a built-in pull up resister, you can test about 0.8V voltage on it. low impulse width > 300ms	This signal switches the module on. The IGT signal characteristic is: Power on triggered and low level triggered. Fall time should be <1ms.
				Note: To turn on the module please use an opendrain/collector circuit
				Test point recommended.
Status signaling	STATUS	0	V _{OI} max = 0.45V at I = 1mA V _{OH} min = 1.35V at I = 1mA V _{OH} max = 1.8V	If unused keep line open.
Emer- gency reset	EMERG_RST	I	Do not add any voltage on it. There is a built-in pull up resistor to pull to GND when Reset.	This line must be driven low by an open drain or open collector driver connected to GND.
			l low impulse width > 200ms	If unused keep line open. Test point recommended.
Fast shut- down	FST_SHDN	I	V _{IL} max = 0.63V V _{IH} min = 1.17V V _{IH} max = 1.8V	This line must be driven low. If unused keep line open.
			l low impulse width > 1ms	Note that the fast shut- down line is originally available as GPIO line. If configured as fast shut- down, the GPIO line is assigned as follows: GPIO4> FST_SHDN
USB	VUSB_IN	I	V _{IN} min = 3V V _{IN} max = 5.25V Active and suspend current: Imax<100μA	All electrical characteristics according to USB Implementers' Forum, USB 2.0 Specification.
	USB_DN	I/O	Full and high speed signal characteris-	If unused keep lines open.
	USB_DP		tics according to USB 2.0 Specification.	Test points recommended.

Table 3: Signal properties (Sheet 3 of 5)

Function	Signal name	Ю	Signal form and level	Comment
Serial Interface ASC0	RXD0	0	V _{OL} max = 0.4V at I = 2mA V _{OH} min = 1.336V at I = -2mA V _{OH} max = 1.93V	If unused keep lines open.
	CTS0			Test points recommended
	DSR0			for RXD0, TXD0, RTS0, and CTS0.
	DCD0			and 0100.
	RING0			
	TXD0	I	V _{IL} max = 0.334V V _{IH} min = 1.351V V _{IH} max = 1.97V	
	RTS0	I	V _{IL} max = 0.334V V _{IH} min = 1.351V V _{IH} max = 1.97V	
	DTR0	I	V _{IL} max = 0.333V V _{IH} min = 1.351V V _{IH} max = 1.97V	
Serial Inter- face ASC1	RXD1	0	V _{OL} max = 0.4V at I = 2mA	If unused keep lines open
	CTS1	0	V _{OH} min = 1.336V at I = -2mA V _{OH} max = 1.93V	Test points recommended
	TXD1	I	V _{IL} max = 0.334V V _{IH} min = 1.351V V _{IH} max = 1.97V	for RXD1, TXD1, RTS1, and CTS1.
	RTS1	I	V _{IL} max = 0.334V V _{IH} min = 1.351V V _{IH} max = 1.97V	

Table 3: Signal properties (Sheet 4 of 5)

Function	Signal name	Ю	Signal form and level	Comment
SIM card detection	CCIN1 CCIN2	I	V _{IH} min = 1.17V V _{IL} max = 0.63V	CCIN = low, SIM card inserted. CCIN= high, SIM card removed.
				If unused keep line open.
3V SIM Card Inter- face	CCRST1 CCRST2	0	V _{OL} max = 0.4V at I= 2mA V _{OH} min = 2.2V at I= -2mA V _{OH} max = 3.04V	Maximum cable length or copper track to SIM card holder should not exceed 100mm.
	CCIO1 CCIO2	I/O	V _{IL} max = 0.55V V _{IH} min = 2.128V V _{IH} max = 3.05V	CCIO2 should add 10k pull-up to CCVCC2
			V_{OL} max = 0.4V at I= 2mA V_{OH} min = 2.2V at I= -2mA V_{OH} max = 3.04V	
	CCCLK1 CCCLK2	0	V_{OL} max = 0.4V at I= 2mA V_{OH} min = 2.2V at I= -2mA V_{OH} max = 3.04V	
	CCVCC1 CCVCC2	0	V_{O} min = 2.75V V_{O} typ = 2.85V V_{O} max = 3.04V I_{O} max = -30mA	
1.8V SIM Card Inter- face	CCRST1 CCRST2	0	V _{OL} max = 0.4V at I = 2mA V _{OH} min = 1.36V at I = -2mA V _{OH} max = 1.93V	Maximum cable length or copper track to SIM card holder should not exceed 100mm.
	CCIO1 CCIO2	I/O	V _{IL} max = 0.334V V _{IH} min = 1.351V V _{IH} max = 1.97V	CCIO2 should add 10k pull-up to CCVCC2
			V _{OL} max = 0.4V at I = 2mA V _{OH} min = 1.336V at I = -2mA V _{OH} max = 1.93V	
	CCCLK1 CCCLK2	0	V _{OL} max = 0.4V at I = 2mA V _{OH} min = 1.336V at I = -2mA V _{OH} max = 1.93V	
	CCVCC1 CCVCC2	0	V_{O} min = 1.67V V_{O} typ = 1.80V V_{O} max = 1.93V I_{O} max = -30mA	

Table 3: Signal properties (Sheet 5 of 5)

Function	Signal name	Ю	Signal form and level	Comment
GPIO interface	GPIO1- GPIO8, GPIO11- GPIO21 GPIO24- GPIO26	Ю	V _{IL} max = 0.334V V _{IH} min = 1.351V V _{IH} max = 1.97V V _{OL} max = 0.4V at I = 2mA V _{IH} min = 1.336V at I = -2mA V _{OH} max = 1.93V	If unused keep line open. Please note that most GPIO lines can be configured by AT command for alternative functions or are by default configured with an alternative functionality: GPIO4: Fast Shut Down (Input) GPIO5: LED status GPIO13: Antenna Switch GPIO26: SIM switch
ADC_IN (Analog-to- Digital Con- verter)	ADC1 ADC2 ADC3	I	R_I = 10Mohm V_I = 0.1V 1.7V (valid range) V_{IH} max = 1.7V Resolution 15 Bits Offset error ±1%	If unused keep line open.
SIM Switch	SIM_SWITCH	0	V_{OL} max = 0.4V at I = 2mA V_{OH} min = 1.336V at I = -2mA V_{OH} max = 1.93V	If unused keep line open.
Power indicator	PWR_IND	0	V _{IH} max = 5.5V V _{OL} max = 0.4V at Imax = 2mA	PWR_IND (Power Indicator) notifies the module's on/off state (see Section 2.1.9). PWR_IND is an open collector that needs to be connected to an external pullup resistor. Low state of the open collector indicates that the module is on. Vice versa, high level notifies the power-down mode. Therefore, the signal may be used to enable external voltage regulators which supply an external logic for communication with the module, e.g. level converters. Do not connect to V180.

2.1.2.1 Absolute Maximum Ratings

The absolute maximum ratings stated in Table 4 are stress ratings under any conditions. Stresses beyond any of these limits will cause permanent damage to PLSx3.

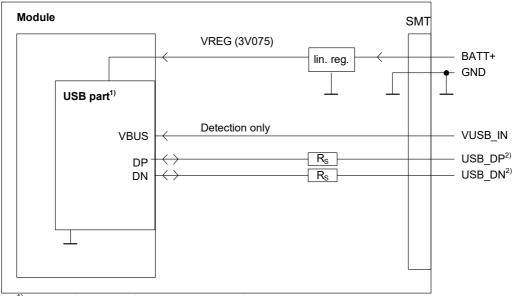
Table 4: Absolute maximum ratings

Parameter	Min	Max	Unit
Supply voltage BATT+ (no service)	-0.3	+5.5	V
Voltage at all digital pins in POWER DOWN mode	-0.3	+0.3	V
Voltage at digital pins 1.8V domain in normal operation	-0.2	V180 + 0.2	V
Voltage at SIM interface, CCVCC 1.8V in normal Operation	0	+2.16	V
Voltage at SIM interface, CCVCC 2.85V in normal Operation	0	+3.25	V
Current at SIM interface in 1.8V and 2.85V operation		-145	mA
Voltage at ADC pin in normal operation	0.1	+1.7*	V
V180 in normal operation	+1.7	+1.9	V
USB-Pins	-0.3	3.63	V

2.1.3 USB Interface

PLSx3 supports a USB 2.0 High Speed (480Mbit/s) device interface that is Full Speed (12Mbit/s) compliant. The impedances, serial and pull up resistors are implemented according to "Universal Serial Bus Specification Revision 2.0", No further additional components are required.

The external application is responsible for supplying the VUSB_IN line. This line is used for cable detection only. The USB part (driver and transceiver) is supplied by means of BATT+. This is because PLSx3 is designed as a self-powered device compliant with the "Universal Serial Bus Specification Revision 2.0".



 $^{^{1)}}$ All serial (including $R_{\!\scriptscriptstyle S}$) and pull-up resistors for data lines are implemented.

Figure 4: USB circuit

To properly connect the module's USB interface to the external application, a USB 2.0 compatible connector and cable or hardware design is required. For more information on the USB related signals see Table 3. Furthermore, the USB modem driver distributed with PLSx3 needs to be installed.

While a USB connection is active, the module will never switch to SLEEP mode. Only if the USB interface is in Suspend mode, the module is able to switch to SLEEP mode.

²⁾ If the USB interface is operated in High Speed mode (480MHz), it is recommended to take special care routing the data lines USB_DP and USB_DN. Application layout should in this case implement a differential impedance of 90 ohms for proper signal integrity.

^{1.} The specification is ready for download on http://www.usb.org/developers/docs/

2.1.3.1 Reducing Power Consumption

While a USB connection is active, the module will never switch into SLEEP mode. Only if the USB interface is in Suspended state or Detached (i.e., VUSB_IN = 0) is the module able to switch into SLEEP mode thereby saving power. There are two possibilities to enable power reduction mechanisms:

Recommended implementation of USB Suspend/Resume/Remote Wakeup:

The USB host should be able to bring its USB interface into the Suspended state as described in the "Universal Serial Bus Specification Revision 2.0". For this functionality to work, the VUSB_IN line should always be kept enabled. On incoming calls and other events PLSx3 will then generate a Remote Wakeup request to resume the USB host controller.

See also [3] (USB Specification Revision 2.0, Section 10.2.7, p.282): "If USB System wishes to place the bus in the Suspended state, it commands the Host Controller to stop all bus traffic, including SOFs. This causes all USB devices to enter the Suspended state. In this state, the USB System may enable the Host Controller to respond to bus wakeup events. This allows the Host Controller to respond to bus wakeup signaling to restart the host system."

• Implementation for legacy USB applications not supporting USB Suspend/Resume: As an alternative to the regular USB suspend and resume mechanism it is possible to employ the RING0 line to wake up the host application in case of incoming calls or events signalized by URCs while the USB interface is in Detached state (i.e., VUSB_IN = 0). Every wakeup event will force a new USB enumeration. Therefore, the external application has to carefully consider the enumeration timings to avoid loosing any signaled events. For details on this host wakeup functionality see Section 2.1.9.4. To prevent existing data call connections from being disconnected while the USB interface is in detached state (i.e., VUS-B IN=0) it is possible to call AT&D0, thus ignoring the status of the DTR line (see also [1]).

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^{1.} The specification is ready for download on http://www.usb.org/developers/docs/

2.1.4 Serial Interface ASC0

PLSx3 offers an 8-wire unbalanced, asynchronous modem interface ASC0 conforming to ITU-T V.24 protocol DCE signaling. The electrical characteristics do not comply with ITU-T V.28. The significant levels are 0V (for low data bit or active state) and 1.8V (for high data bit or inactive state). For electrical characteristics please refer to Table 3.

PLSx3 is designed for use as a DCE. Based on the conventions for DCE-DTE connections it communicates with the customer application (DTE) using the following signals:

- Port TXD @ application sends data to the module's TXD0 signal line
- Port RXD @ application receives data from the module's RXD0 signal line

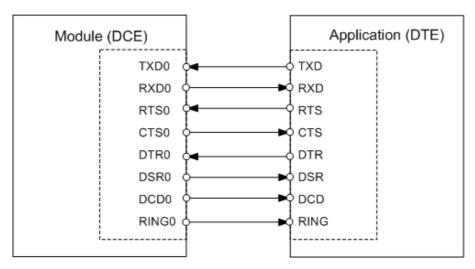


Figure 5: Serial interface ASC0

Features:

- Includes the data lines TXD0 and RXD0, the status lines RTS0 and CTS0 and, in addition, the modem control lines DTR0, DSR0, DCD0 and RING0.
- The RING0 signal serves to indicate incoming calls and other types of URCs (Unsolicited Result Code). It can also be used to send pulses to the host application, for example to wake up the application from power saving state.
- Configured for 8 data bits, no parity and 1 stop bit.
- ASC0 can be operated at fixed bit rates from 300bps up to 921600bps and 3M.
- Supports RTS0/CTS0 hardware flow control. The hardware hand shake line RTS0 has an
 internal pull down resistor causing a low level signal, if the line is not used and open.
 Although hardware flow control is recommended, this allows communication by using only
 RXD and TXD lines.
- Wake up from SLEEP mode by RTS0 activation (high to low transition; see Section 3.3.4)

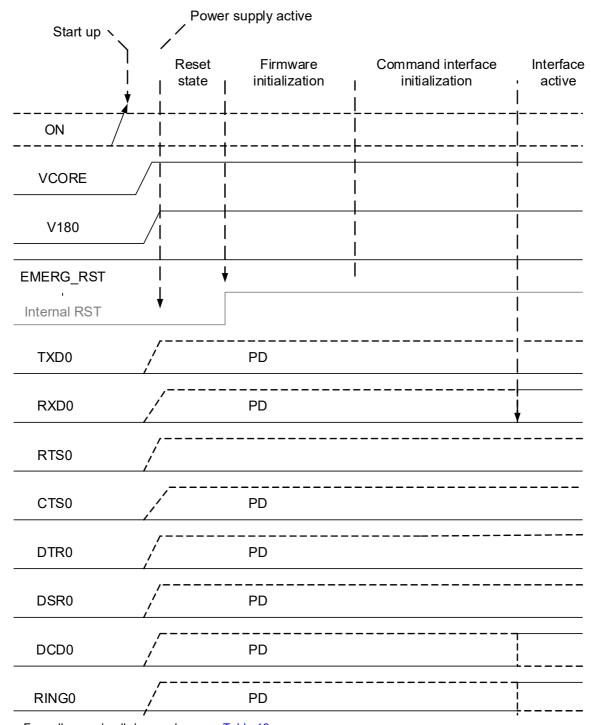
Note: The ASC0 modem control lines DTR0, DCD0, DSR0 and RING0 can also be configured as GPIO lines. If configured as GPIO lines, these GPIO lines are assigned as follows:

GPIO1-->DTR0 GPIO2-->DCD0 GPIO3-->DSR0 GPIO24-->RING0

Configuration is done by AT command (see [1]). The configuration is non-volatile and becomes active after a module restart.

Notes: No data must be sent over the ASC0 interface before the interface is active and ready to receive data (see Section 3.2.1).

The following figure shows the startup behavior of the asynchronous serial interface ASC0.



For pull-up and pull-down values see Table 13.

Figure 6: ASC0 startup behavior

2.1.5 Serial Interface ASC1

Four PLSx3 GPIO lines can be configured as ASC1 interface signals to provide a 4-wire unbalanced, asynchronous interface ASC1 conforming to ITU-T V.24 protocol DCE signalling. The electrical characteristics do not comply with ITU-T V.28. The significant levels are 0V (for low data bit or active state) and 1.8V (for high data bit or inactive state). For electrical characteristics please refer to Table 3.

PLSx3 is designed for use as a DCE. Based on the conventions for DCE-DTE connections it communicates with the customer application (DTE) using the following signals:

- Port TXD @ application sends data to module's TXD1 signal line
- Port RXD @ application receives data from the module's RXD1 signal line

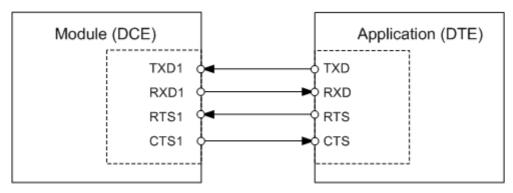


Figure 7: Serial interface ASC1

Features

- Includes only the data lines TXD1 and RXD1 plus RTS1 and CTS1 for hardware handshake.
- On ASC1 no RING line is available.
- Configured for 8 data bits, no parity and 1 or 2 stop bits.
- ASC1 can be operated at fixed bit rates from 300 bps to 921,600bps.
- Supports RTS1/CTS1 hardware flow. The hardware hand shake line RTS1 has an internal pull down resistor causing a low level signal, if the line is not used and open. Although hardware flow control is recommended, this allows communication by using only RXD and TXD lines.

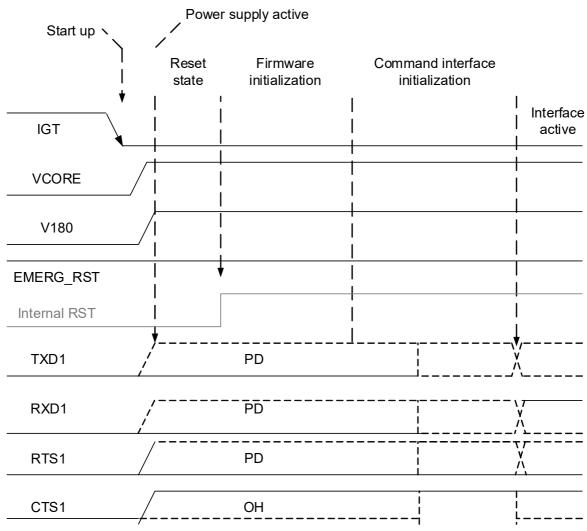
Notes: The ASC1 interface lines are originally available as GPIO lines. If configured as ASC1 lines, the GPIO lines are assigned as follows:

GPIO16-->RXD1 GPIO17-->TXD1 GPIO18-->RTS1

GPIO19-->CTS1

Configuration is done by AT command (see [1]). The configuration is non-volatile and becomes active after a module restart.

The following figure shows the startup behavior of the asynchronous serial interface ASC1.



For pull-down values see Table 13.

Figure 8: ASC1 startup behavior

2.1.6 UICC/SIM/USIM Interface

PLSx3 has two UICC/SIM/USIM interfaces (includes eSIM interface) compatible with the 3GPP 31.102 and ETSI 102 221. These are wired to the host interface in order to be connected to an external SIM card holder. Five pads on the SMT application interface are reserved for each of the two SIM interfaces.

The UICC/SIM/USIM interface supports 3V and 1.8V SIM cards. Please refer to Table 3 for electrical specifications of the UICC/SIM/USIM interface lines depending on whether a 3V or 1.8V SIM card is used.

The CCINx signal serves to detect whether a tray (with SIM card) is present in the card holder. Using the CCINx signal is mandatory for compliance with the GSM 11.11 recommendation if the mechanical design of the host application allows the user to remove the SIM card during operation. To take advantage of this feature, an appropriate SIM card detect switch is required on the card holder. See Chapter 7.1 as example for a card holder with an internal switch.

Table 5: Signals of the SIM interface (SMT application interface)

Signal	Description
GND	Ground connection for SIM interfaces. Optionally a separate SIM ground line using e.g., pad N11, may be used to improve EMC.
CCCLK1 CCCLK2	Chipcard clock lines for 1 st and 2 nd SIM interface.
CCVCC1 CCVCC2	SIM supply voltage lines for 1 st and 2 nd SIM interface.
CCIO1 CCIO2	Serial data lines for 1 st and 2 nd SIM interface, input and output.
CCRST1 CCRST2	Chipcard reset lines for 1 st and 2 nd SIM interface.
CCIN1 CCIN2	Input on the baseband processor for detecting a SIM card tray in the holder. If the SIM is removed during operation the SIM interface is shut down immediately to prevent destruction of the SIM. The CCINx signal is active low. The CCINx signal is mandatory for applications that allow the user to remove the SIM card during operation. The CCINx signal is solely intended for use with a SIM card. It must not be used for any other purposes. Failure to comply with this requirement may invalidate the type approval of PLSx3.

Note: No guarantee can be given, nor any liability accepted, if loss of data is encountered after removing the SIM card during operation. Also, no guarantee can be given for properly initializing any SIM card that the user inserts after having removed the SIM card during operation. In this case, the application must restart PLSx3.

By default, only the module's 1st SIM interface is available and can be used. The usage of the module's 2nd SIM interface has to be configured by AT command.

As an alternative to connecting the module's two SIM interfaces and switching between these via AT command, it is possible to connect the first of the module's SIM interfaces via an external SIM switch that in turn provides access to a further SIM interface. For details see Section 2.1.6.2.

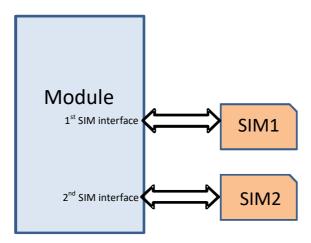


Figure 9: Module's two UICC/SIM/USIM interfaces

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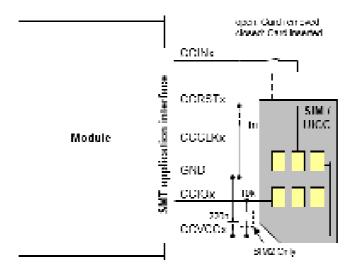


Figure 10: UICC/SIM/USIM interfaces connected

The total cable length between the SMT application interface pads on PLSx3 and the pads of the external SIM card holder must not exceed 100mm in order to meet the specifications of 3GPP TS 51.010-1 and to satisfy the requirements of EMC compliance.

To avoid possible cross-talk from the CCCLKx signal to the CCIOx signal be careful that both lines are not placed closely next to each other. A useful approach is using the GND line to shield the CCIOx line from the CCCLKx line.

2.1.6.1 Enhanced ESD Protection for SIM Interface

To optimize ESD protection for the SIM interface it is possible to add ESD diodes (eg. NUP4114) to the SIM interface lines as shown in the example given in Figure 11. Please place the ESD protection close to the SIM connector. It is suggested that the cload of diode be less than 3pF.

The example was designed to meet ESD protection according ETSI EN 301 489-1/7: Contact discharge: ± 4kV, air discharge: ± 8kV.

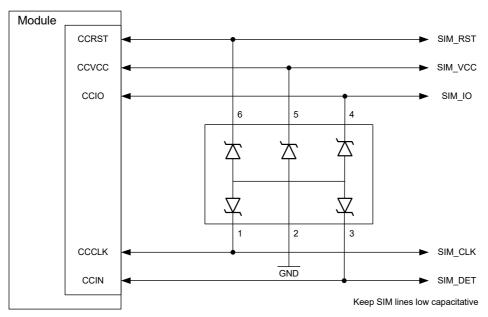


Figure 11: SIM interface - enhanced ESD protection

2.1.6.2 SIM_SWITCH Line

As an alternative to connecting the module's two SIM interfaces and switching between these interfaces by means of AT command, it is possible to connect the first of the module's SIM interfaces via an external SIM switch that in turn provides access to a further SIM interface.

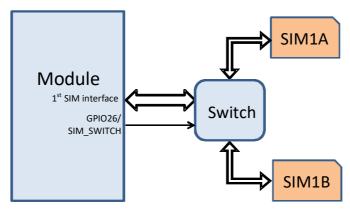


Figure 12: External UICC/SIM/USIM switch

The module's GPIO26 line can in this case be configured as SIM_SWITCH line in order to control the external SIM switch as shown in the sample circuit in Figure 13. A low state would then indicate the usage of the first SIM interface (SIM1A), a high state would indicate the usage of the second interface (SIM1B).

The configuration of the SIM_SWITCH (GPIO26) line is done via AT command, is non-volatile, and available after the next module restart.

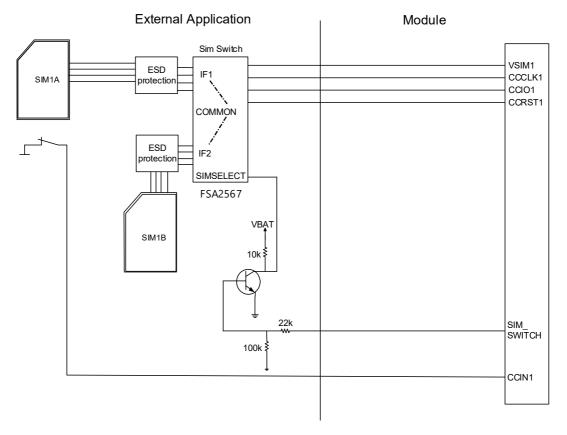


Figure 13: Sample circuit for SIM interface connection via SIM switch

2.1.7 **GPIO** Interface

PLSx3 offers a GPIO interface with 22 GPIO lines. The GPIO lines are shared with other interfaces or functions: Fast shutdown (see Section 2.1.9.3), Status LED (see Section 2.1.9.1), ASC0 (see Section 2.1.4), ASC1 (see Section 2.1.5) and SIM Switch (see Section 2.1.6.2)

The following table shows the configuration variants for the GPIO pads. All variants are mutually exclusive, i.e. a pad configured for instance as Status LED is locked for alternative usage.

Table 6: GPIO lines and possible alternative assignment

GPIO	Fast Shutdown	Status LED	ASC0	ASC1	SIM SWITCH
GPIO1			DTR0		
GPIO2			DCD0		
GPIO3			DSR0		
GPIO4	FST_SHDN				
GPIO5		Status LED			
GPIO6					
GPIO7					
GPIO8					
GPIO11					
GPIO12					
GPIO13					
GPIO14					
GPIO15					
GPIO16				RXD1	
GPIO17				TXD1	
GPIO18				RTS1	
GPIO19				CTS1	
GPIO20					
GPIO21					
GPIO24			RING0		
GPIO25					
GPIO26					SIM_SWITCH

The following figure shows the startup behavior of the GPIO interface.

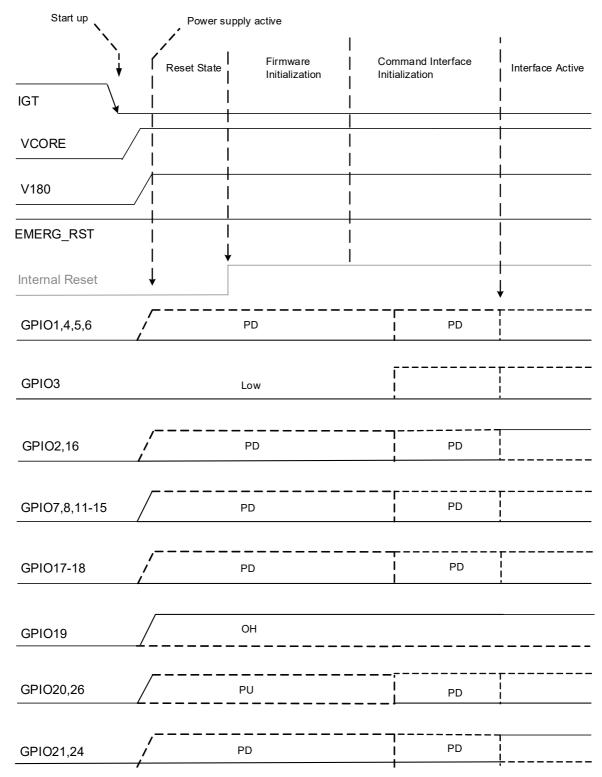


Figure 14: GPIO startup behavior

2.1.8 Analog-to-Digital Converter (ADC)

PLSx3 provides three unbalanced ADC input line: ADC[1...3]_IN. They can be used to measure three independent, externally connected DC voltages in the range of 0.1V to 1.7V. They can be used especially for antenna diagnosing.

The AT^SRADC command can be employed to select the ADC line, set the measurement mode and read out the measurement results.

2.1.9 Control Signals

2.1.9.1 Status LED

The GPIO5 interface line can be configured to drive a status LED that indicates different operating mode (for GPIOs see 2.1.7). GPIO and LED functionality are mutually exclusive.

To take advantage of this function connect an LED to the GPIO5/STATUS line as shown in Figure 15

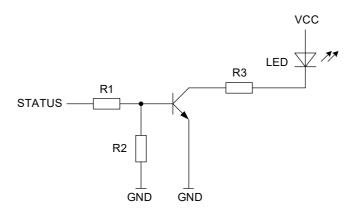


Figure 15: Status signaling with LED driver

2.1.9.2 Power Indication

The power indication signal PWR_IND notifies the on/off state of the module. High state of PWR_IND indicates that the module is switched off. The state of PWR_IND immediately changes to low when IGT is pulled low. For state detection an external pull-up resistor is required.

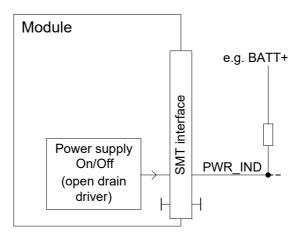


Figure 16: Power indication signal

2.1.9.3 Fast Shutdown

The FST_SHDN line triggers the module's fast shutdown procedure. The fast shutdown procedure ensure data integrity during shutdown, but will no longer deregister gracefully from the network thus saving the time normally required for network deregistration.

The FST_SHDN is an active low control signal and must be applied via an open drain or open collector circuit. It is recommended to verify the behavior of the external application especially during the boot and initialization phase against back powering and unintentional fast shutdown.

It is recommended to keep the FST_SHDN line low until the module has shut down. A low level of the V180 signal indicates that the module has entered the Power Down mode. No shutdown URC will be issued with a fast shutdown. Thus, it is recommended to monitor the V180 line by the external application. Other reference voltage lines may still show a high level.

Once V180 is low, the external application can cut the module's power supply.

In order not to trigger a restart loop of the module, the ON line shall be released by the external application, and not be actively driven continuously.

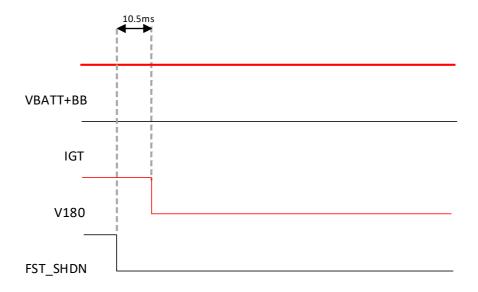


Figure 17: Fast shutdown timing

If the FST_SHDN functionality is not used, the FST_SHDN line can be left open because of a configured internal pull-up resistor.

If there is a reasonable probability for sudden power losses, Thales recommends to implement a circuit using the FST_SHDN line with a capacitor to buffer sufficient energy to complete the fast shutdown - see below for sample capacity calculation.

Please note that the normal software controlled shutdown via AT^SMSO can also be configured as a fast shutdown, i.e., without network deregistration. For details see [1].

Sample Capacity Calculation:

The following formula is a guideline for a capacitor required in a fast shutdown circuit to buffer enough energy to complete the fast shutdown process.

Depending on the application design and use case the factors may vary.

Capacitor energy:

E[J]= 0.5xC * (V^2max-V^2-min) * Aging factor

Example:

Aging factor e.g = 0.7

 $E[J] = 0.5 * 2500 uF * ((4.5V)^2 - (3.0V)^2) * 0.7 = 0.0098J$

Note: Vmax can be limited by the module supply and/or capacitor voltage. Same applies for the Vmin which is mostly limited by VBATT min.

Module energy usage:

Vavg = Vmax + Vmin / 2

Aavg = See typical values in Section 3.4.1.

E[W] = Vavg * Aavg * Efficiency

Example:

Power Circuit Efficiency factor, e.g = 0.8

E[W] = ((4.5V + 3.0V) / 2) * 0.2A * 0.8 = 0.6375W (assuming the Cat NB1/2 worst case)

Discharge time:

T[s] = E[J] / E[W]

Example:

T[s] = 0.0098J / 0.6375W = 0.015s

2.1.9.4 Remote Wakeup

If no call, data or message transfer is in progress, the external host application may shut down its own module interfaces or other components in order to save power. If a call, data, or other request (URC) arrives, the external application can be notified of this event and be woken up again by a state transition of a configurable remote wakeup line. Available as remote wakeup lines are some GPIO signals (recommended is GPIO24). Please refer to [1]: AT^SCFG: "RemoteWakeUp/..." for details on how to configure these lines for defined wakeup events on specified device interfaces. Possible states are listed in Table 7.

If no line is specifically configured as remote wakeup signal, the remote USB suspend and resume mechanism as specified in the "Universal Serial Bus Specification Revision 2.0" applies for the USB interface (see Section 2.1.3). Possible states for the remote wakeup GPIO lines are listed in Table 7.

Table 7: Remote wakeup lines

Signal	I/O/P	Description
GPIOx	0	Inactive to active high transition: 0 = No wake up request 1 = The host shall wake up

2.1.9.5 Antenna Switch

The GPIO13 interface can be configured as antenna switch signal line ANT_SWITCH. The ANT_SWITCH line can act as a control signal for a possible external antenna switch that is able to change between an antenna covering the defined frequency range and an antenna covering all other frequency range currently being used by the module.

The ANT_SWITCH line sets to "1" if the module employing any RX/TX frequencies in the defined frequency range, and "0" for all the other frequencies.

The frequency range which will be indicated by signal lines is configured AT^SCFG="Radio/AntTun/1",<mask1>[,<mask2]. For more information please refer to [1] for more details.

The switching function will be triggered by all internal activities involving a change of used frequency, even if only temporary (e.g. inter-band scanning using compressed mode). The maximum permissible delay/deviation between internal usage of the frequency band is defined by the internal setting of the front-end switch and setting of the GPIO13 will be within 10 microsecond.

For electrical characteristics of the ANT SWITCH line see Table 3.

2.2 RF Antenna Interface

The PLSx3 GSM/UMTS/LTE antenna interface comprises a GSM/UMTS/LTE main antenna as well as a UMTS/LTE Rx diversity antenna to improve signal reliability and quality¹. The RF interface has an impedance of 50Ω. PLSx3 is capable of sustaining a total mismatch at the antenna line without any damage, even when transmitting at maximum RF power.

The external antenna must be matched properly to achieve best performance regarding radiated power, modulation accuracy and harmonic suppression. Antenna matching networks are not included on the PLSx3 module and should be placed in the host application if the antenna does not have an impedance of 50Ω .

Regarding the return loss PLSx3 provides the following values in the active band:

Table 8: Return loss in the active band

State of module	Return loss of module	Recommended return loss of application
Receive	≥ 8dB	≥ 12dB
Transmit	not applicable	≥ 12dB

^{1.} By delivery default the UMTS/LTE Rx diversity antenna is configured as available for the module since its usage is mandatory for LTE. Please refer to [1] for details on how to configure antenna settings.

2.2.1 Antenna Interface Specifications

Table 9: RF Antenna interface GSM/UMTS/LTE

Parameter	Conditions	Min.	Typical	Max.	Unit
LTE connectivity for -W, EP, LA, I,J)	Band 1,2,3,4,5,7,8,12,13,17	,18,19,20,2	26,28,38,4	0,41,66,	
Receiver Input Sensitivity	LTE FDD 2100 Band 1	-100.0	-104.3		dBm
@ARP, Combined Antenna, Channel BW at 5 MHz	LTE FDD 1900 Band 2	-98.0	-104.7		dBm
@25°C, 3.8V	LTE FDD 1800 Band 3	-97.0	-104.3		dBm
	LTE FDD 2100 Band 4	-100.0	-104.1		dBm
	LTE FDD 850 Band 5	-98.0	-103.4		dBm
	LTE FDD 2600 Band 7	-98.0	-102.2		dBm
	LTE FDD 900 Band 8	-97.0	-104.1		dBm
	LTE FDD 700 Band 12	-97.0	-104.8		dBm
	LTE FDD 700 Band 13	-97.0	-105.0		dBm
	LTE FDD 700 Band 17	-97.0	-104.4		dBm
	LTE FDD 850 Band 18	-98.0	-103.3		dBm
	LTE FDD 850 Band 19	-100.0	-102.7		dBm
	LTE FDD 800 Band 20	-97.0	-104.5		dBm
	LTE FDD 850 Band 26	-98.0	-103.1		dBm
	LTE FDD 700 Band 28	-98.5	-104.9		dBm
	LTE TDD 2600 Band 38	-100.0	-103.6		dBm
	LTE TDD 2300 Band 40	-100.0	-104.6		dBm
	LTE TDD 2500 Band 41	-98.0	-103.5		dBm
	LTE FDD 2100 Band 66	-99.5	-104.0		dBm
LTE connectivity for - X,X2,X3,X4	Band 2,4,5,12,13,14,25,26,6	66,71			
Receiver Input Sensitivity	LTE FDD 1900 Band 2	-98.0	-103.5		dBm
@ARP, Combined Antenna, Channel BW at 5 MHz	LTE FDD 2100 Band 4	-100.0	-103.3		dBm
@25°C, 3.8V	LTE FDD 850 Band 5	-98.0	-105.0		dBm
	LTE FDD 700 Band 12	-97.0	-104.6		dBm
	LTE FDD 700 Band 13	-97.0	-104.9		dBm
	LTE FDD 700 Band 14	-97.0	-104.2		dBm
	LTE FDD 1900 Band 25	-96.5	-103.4		dBm
	LTE FDD 850 Band 26	-98.0	-105.0		dBm
	LTE FDD 2100 Band 66	-99.5	-103.1		dBm
	LTE FDD 600 Band 71	-97.2	-104.4		dBm

Table 9: RF Antenna interface GSM/UMTS/LTE

Parameter	Conditions	Min.	Typical	Max.	Unit
RF Power @ARP with 50Ω	LTE FDD 2100 Band 1	+21	+23.0		dBm
Load (Board	LTE FDD 1900 Band 2	+21	+23.0		dBm
temperature<85°C, 5 MHz BW, 1RB Position Low)	LTE FDD 1800 Band 3	+21	+23.0		dBm
BVV, TVB T GOIGOTT LOW)	LTE FDD 2100 Band 4	+21	+23.0		dBm
	LTE FDD 850 Band 5	+21	+23.0		dBm
	LTE FDD 2600 Band 7	+21	+22.5		dBm
	LTE FDD 900 Band 8	+21	+23.0		dBm
	LTE FDD 700 Band 12	+21	+23.0		dBm
	LTE FDD 700 Band 13	+21	+23.0		dBm
	LTE FDD 700 Band 14	+21	+23.0		dBm
	LTE FDD 700 Band 17	+21	+23.0		dBm
	LTE FDD 850 Band 18	+21	+23.0		dBm
	LTE FDD 850 Band 19	+21	+23.0		dBm
	LTE FDD 800 Band 20	+21	+23.0		dBm
	LTE FDD 1900 Band 25	+21	+23.0		dBm
	LTE FDD 850 Band 26	+21	+23.0		dBm
	LTE FDD 700 Band 28	+21	+23.0		dBm
	LTE TDD 2600 Band 38	+21	+23.0		dBm
	LTE TDD 2300 Band 40	+21	+23.0		dBm
	LTE TDD 2500 Band 41	+21	+23.0		dBm
	LTE FDD 2100 Band 66	+21	+23.0		dBm
	LTE FDD 600 Band 71	+21	+23.0		dBm

Table 9: RF Antenna interface GSM/UMTS/LTE

Parameter	Conditions	Min.	Typical	Max.	Unit
UMTS connectivity	Band I,II,III, IV,V,VI,VIII,X	<u> </u>		<u>'</u>	
Receiver Input Main Sensi-	UMTS 2100 Band I	-106.7	-110.2		dBm
tivity @ ARP @25°C, 3.8V	UMTS 1900 Band II	-104.7	-111.3		dBm
	UMTS 1800 Band III	-103.7	-110.6		dBm
	UMTS 2100 Band IV	-106.7	-110.3		dBm
	UMTS 850 Band V	-104.7	-110.9		dBm
	UMTS 850 Band VI	-106.7	-110.2		dBm
	UMTS 900 Band VIII	-103.7	-110.5		dBm
	UMTS 850 Band XIX	-106.7	-110.5		dBm
Receiver Input Diversity	UMTS 2100 Band I	-106.7	-111.5		dBm
Sensitivity @ ARP @25°C, 3.8V	UMTS 1900 Band II	-104.7	-111.6		dBm
	UMTS 1800 Band III	-103.7	-112.1		dBm
	UMTS 2100 Band IV	-106.7	-111.8		dBm
	UMTS 850 Band V	-104.7	-112.0		dBm
	UMTS 850 Band VI -106.7 -111.3			dBm	
	UMTS 900 Band VIII	-103.7	-111.8		dBm
	UMTS 850 Band XIX	-106.7	-111.1		dBm
RF Power @ ARP with	UMTS 2100 Band I	+21	+23.5		dBm
50Ohm Load Board temperature < 85°C	UMTS 1900 Band II	+21	+23.5		dBm
board temperature 100 0	UMTS 1800 Band III	+21	+23.5		dBm
	UMTS 1700 Band IV	+21	+23.5		dBm
	UMTS 850 Band V	+21	+23.5		dBm
	UMTS 850 Band VI	+21	+23.5		dBm
	UMTS 900 Band VIII	+21	+23.5		dBm
	UMTS 850 Band XIX	+21	+23.5		dBm
GPRS coding schemes	Class 12, CS1 to CS4	·			
EGPRS	Class 12, MCS1 to MCS9)			
GSM Class	Small MS				
Static Receiver input Sensi-	GSM 850	-102.0	-108.6		dBm
tivity @ ARP	E-GSM 900	-102.0	-108.9		dBm
	DCS 1800	-102.0	-109.6		dBm
	PCS 1900	-102.0	-109.6		dBm
RF Power @ ARP	GSM 850		33		dBm
with 500hm Load Board temperature < 85°C	E-GSM 900		33		dBm
,	DCS 1800		30		dBm
	PCS 1900		30		dBm

Table 9: RF Antenna interface GSM/UMTS/LTE

Parameter	Conditions		Min.	Typical	Max.	Unit
RF Power @ ARP	GPRS, 1 TX	GSM 850		33		dBm
with 500hm Load, (ROPR = 4, i.e. no reduction)		E-GSM 900		33		dBm
(ROPR = 4 , i.e. no reduction)		DCS 1800		30		dBm
		PCS 1900		30		dBm
	EDGE, 1 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 2 TX	GSM 850		33		dBm
		E-GSM 900		33		dBm
		DCS 1800		30		dBm
		PCS 1900		30		dBm
	EDGE, 2 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 3 TX	GSM 850		33		dBm
		E-GSM 900		33		dBm
		DCS 1800		30		dBm
		PCS 1900		30		dBm
	EDGE, 3 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 4 TX	GSM 850		33		dBm
		E-GSM 900		33		dBm
		DCS 1800		30		dBm
		PCS 1900		30		dBm
	EDGE, 4 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm

Table 9: RF Antenna interface GSM/UMTS/LTE

Parameter	Conditions		Min.	Typical	Max.	Unit
RF Power @ ARP	GPRS, 1 TX	GSM 850		33		dBm
with 500hm Load,		E-GSM 900		33		dBm
(ROPR =5, i.e. partial reduction)		DCS 1800		30		dBm
		PCS 1900		30		dBm
	EDGE, 1 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 2 TX	GSM 850		33		dBm
		E-GSM 900		33		dBm
		DCS 1800		30		dBm
		PCS 1900		30		dBm
	EDGE, 2 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 3 TX	GSM 850		32.2		dBm
		E-GSM 900		32.2		dBm
		DCS 1800		29.2		dBm
		PCS 1900		29.2		dBm
	EDGE, 3 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 4 TX	GSM 850		31		dBm
		E-GSM 900		31		dBm
		DCS 1800		28		dBm
		PCS 1900		28		dBm
	EDGE, 4 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm

Table 9: RF Antenna interface GSM/UMTS/LTE

Parameter	Conditions		Min.	Typical	Max.	Unit
RF Power @ ARP	GPRS, 1 TX	GSM 850		33		dBm
with 500hm Load,		E-GSM 900		33		dBm
(ROPR = 6, i.e. partial reduction)		DCS 1800		30		dBm
		PCS 1900		30		dBm
	EDGE, 1 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 2 TX	GSM 850		32		dBm
		E-GSM 900		32		dBm
		DCS 1800		29		dBm
		PCS 1900		29		dBm
	EDGE, 2 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 3 TX	GSM 850		30.2		dBm
		E-GSM 900		30.2		dBm
		DCS 1800		27.2		dBm
		PCS 1900		27.2		dBm
	EDGE, 3 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 4 TX	GSM 850		29		dBm
		E-GSM 900		29		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	EDGE, 4 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm

Table 9: RF Antenna interface GSM/UMTS/LTE

Parameter	Conditions		Min.	Typical	Max.	Unit
RF Power @ ARP	GPRS, 1 TX	GSM 850		33		dBm
with 500hm Load,		E-GSM 900		33		dBm
(ROPR = 7 , i.e. partial reduction)		DCS 1800		30		dBm
,		PCS 1900		30		dBm
	EDGE, 1 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 2 TX	GSM 850		30		dBm
		E-GSM 900		30		dBm
		DCS 1800		27		dBm
		PCS 1900		27		dBm
	EDGE, 2 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 3 TX	GSM 850		28.2		dBm
		E-GSM 900		28.2		dBm
		DCS 1800		25.2		dBm
		PCS 1900		25.2		dBm
	EDGE, 3 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 4 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		24		dBm
		PCS 1900		24		dBm
	EDGE, 4 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm

Table 9: RF Antenna interface GSM/UMTS/LTE

Parameter	Conditions		Min.	Typical	Max.	Unit
RF Power @ ARP	GPRS, 1 TX	GSM 850		33		dBm
with 500hm Load,		E-GSM 900		33		dBm
(ROPR = 8, i.e. max reduction)		DCS 1800		30		dBm
		PCS 1900		30		dBm
	EDGE, 1 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		26		dBm
		PCS 1900		26		dBm
	GPRS, 2 TX	GSM 850		30		dBm
		E-GSM 900		30		dBm
		DCS 1800		27		dBm
		PCS 1900		27		dBm
	EDGE, 2 TX	GSM 850		24		dBm
		E-GSM 900		24		dBm
		DCS 1800		23		dBm
		PCS 1900		23		dBm
	GPRS, 3 TX	GSM 850		28.2		dBm
		E-GSM 900		28.2		dBm
		DCS 1800		25.2		dBm
		PCS 1900		25.2		dBm
	EDGE, 3 TX	GSM 850		22.2		dBm
		E-GSM 900		22.2		dBm
		DCS 1800		21.2		dBm
		PCS 1900		21.2		dBm
	GPRS, 4 TX	GSM 850		27		dBm
		E-GSM 900		27		dBm
		DCS 1800		24		dBm
		PCS 1900		24		dBm
	EDGE, 4 TX	GSM 850		21		dBm
		E-GSM 900		21		dBm
		DCS 1800		20		dBm
		PCS 1900		20		dBm

2.2.2 Antenna Installation

The antenna is connected by soldering the antenna pads (ANT_MAIN, ANT_DRX and ANT_GNSS) and their neighboring ground pads directly to the application's PCB.

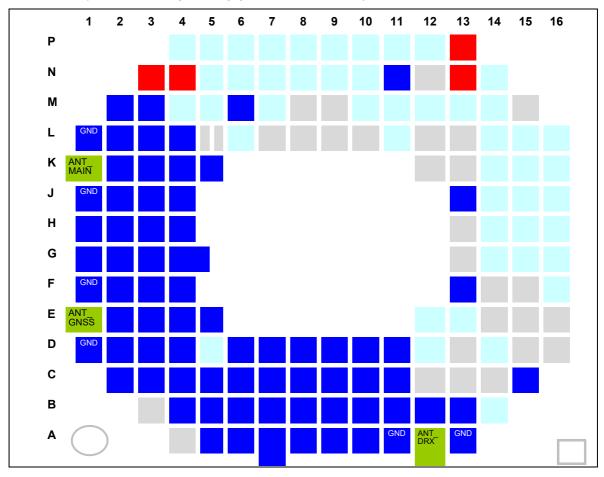


Figure 18: Antenna pads (bottom view)

The distance between the antenna pads and their neighboring GND pads has been optimized for best possible impedance. To prevent mismatch, special attention should be paid to these pads on the application' PCB.

The wiring of the antenna connection, starting from the antenna pad to the application's antenna should result in a 50Ω line impedance. Line width and distance to the GND plane need to be optimized with regard to the PCB's layer stack. Some examples are given in Section 2.2.3.

To prevent receiver desensitization due to interferences generated by fast transients like high speed clocks on the external application PCB, it is recommended to realize the antenna connection line using embedded Stripline rather than Micro-Stripline technology. Please see Section 2.2.3 for examples of how to design the antenna connection in order to achieve the required 50Ω line impedance.

For type approval purposes, the use of a 50Ω coaxial antenna connector (U.FL-R-SMT) might be necessary. In this case the U.FL-R-SMT connector should be placed as close as possible to PLSx3's antenna pad.

2.2.3 RF Line Routing Design

2.2.3.1 Line Arrangement Examples

Several dedicated tools are available to calculate line arrangements for specific applications and PCB materials - for example from http://www.polarinstruments.com/ (commercial software) or from https://www.awr.com/awr-software/options/tx-line or https://saturnpcb.com/saturn-pcb-toolkit/ (free software).

Embedded Stripline

This figure below shows a line arrangement example for embedded stripline.



Figure 19: Embedded stripline arrangement example

Micro-Stripline

This section gives two line arrangement examples for micro-stripline.



Figure 20: Micro-Stripline arrangement example

2.2.3.2 Routing Example

Interface to RF Connector

Figure 21 and Figure 22 show a sample connection of a module's antenna pad at the bottom layer of the module PCB with an application PCB's coaxial antenna connector. Line impedance depends on line width, but also on other PCB characteristics like dielectric, height and layer gap. The sample stripline width of 0.33mm/0.8mm and the space of 0.625mm/0.173mm are only recommended for an application with a PCB layer stack resembling the one of the PLSx3 evaluation board, and with layer 2 as well as layer 3 cut clear. For different layer stacks the stripline width will have to follow stripline routing rules, avoiding 90 degree corners and using the shortest distance to the PCB's coaxial antenna connector.

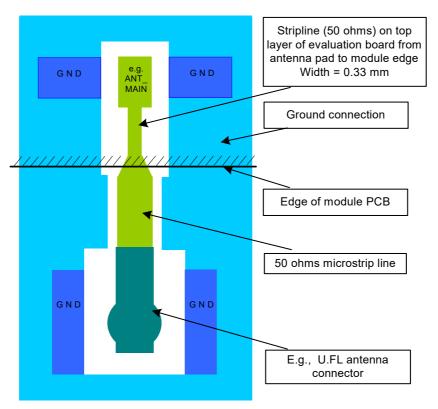


Figure 21: Routing to application's RF connector

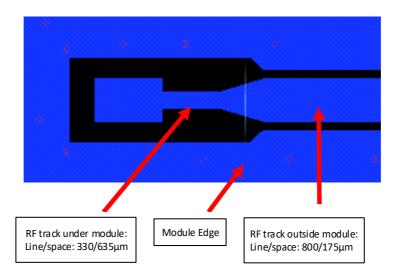


Figure 22: Routing Detail

2.3 GNSS Antenna Interface

2.3.1 GNSS Receiver

PLSx3 integrates a GNSS receiver that offers the full performance of GPS/GLONASS/BeiDou/Galileo/QZSS technology. The GNSS receiver is able to continuously track all satellites in view, thus providing accurate satellite position data.

The integrated GNSS receiver supports the NMEA protocol. NMEA is a combined electrical and data specification for communication between various (marine) electronic devices including GNSS receivers. It has been defined and controlled by the US based National Marine Electronics Association. For more information on the NMEA Standard please refer to http://www.nmea.org.

Depending on the receiver's knowledge of last position, current time and ephemeris data, the receiver's startup time (i.e., TTFF = Time-To-First-Fix) may vary: If the receiver has no knowledge of its last position or time, a startup takes considerably longer than if the receiver still has knowledge of its last position, time and almanac or has still access to valid ephemeris data and the precise time. For more information see Section 2.3.4. Often, 2D measurements will be used over 3D depending on space vehicle (SV) locations as this will be just as accurate and faster.

By default, the GNSS receiver is switched off. It has to be switched on and configured using AT commands (AT^SGPSC; see[1]).

2.3.2 GNSS Antenna

In addition to the RF antenna interface PLSx3 also has a GNSS antenna interface. See Section 2.1.1 to find out where the GNSS antenna pad is located. The GNSS pad's shape is the same as for the RF antenna interface (see Section 2.2.2).

It is possible to connect active or passive GNSS antennas. In either case they must have 50Ω impedance. The simultaneous operation of GSM/UMTS/LTE and GNSS is implemented. For electrical characteristics see Section 2.2.

PLSx3 provides the signal VGNSS to enable an active GNSS antenna power supply. Figure 23 shows the flexibility in realizing the power supply for an active GNSS antenna by giving a sample circuit realizing the supply voltage for an active GNSS antenna.

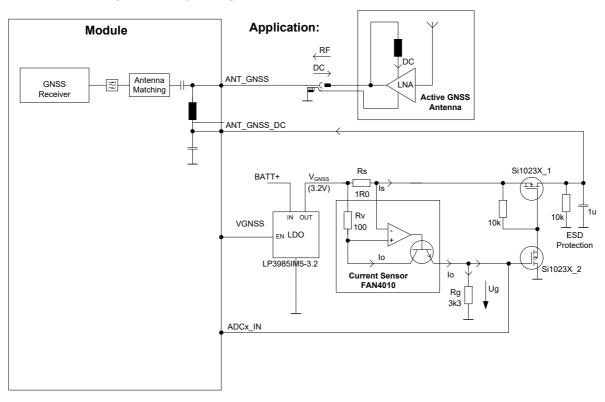


Figure 23: Supply voltage for active GNSS antenna

Figure 24 shows a sample circuit realizing ESD protection for a passive GNSS antenna. Connecting the input ANT_GNSS_DC to GND prevents ESD from coupling into the module.

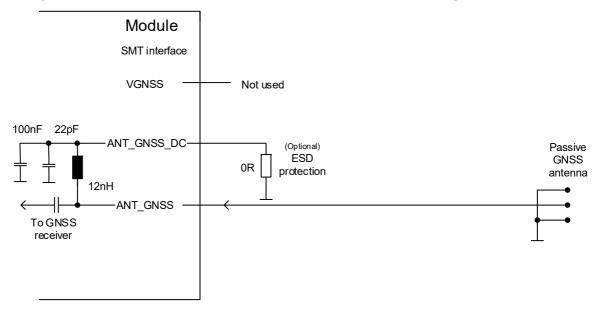


Figure 24: ESD protection for passive GNSS antenna

2.3.3 GNSS Antenna Diagnostic

GNSS antenna diagnosis does require an external detection circuit. The antenna DC supply current can be measured via ADCx_IN. The ADCx_IN input voltage (Ug) may be generated by a sample circuit shown in Figure 23. The circuit allows to check the presence and the connection status of an active GNSS antenna. Passive GNSS antennas cannot be detected. Therefore, GNSS antenna detection is only available in active GNSS antenna mode. This mode is configured by the AT command: AT^SGPSC (for details see [1])

Having enabled the active GNSS antenna mode the presence and connection status of an active GNSS antenna can be checked using the AT command AT^SRADC to monitor ADCx_IN. The following table lists sample current ranges for possible antenna states as well as sample voltage ranges as possible decision thresholds to distinguish between the antenna connection states. Please refer to [1] for more information on the command AT^SRADC.

Table 10: Sample ranges of the GNSS antenna diagnostic measurements and their possible meaning

Antenna connection status	Current ranges (I _S) ¹	Voltage ranges (U _G)
Antenna not connected	<1.4mA	
Decision threshold		59mV ±20%
Antenna connected	2.2mA20mA	
Decision threshold		825mV ±20%
Antenna short circuited to ground	>30mA	
GNSS antenna detection is not possible because GNSS antenna power supply is switched off.		

^{1.} Please note that the mA ranges 1.4mA...2.2mA and 20mA...30mA are tolerance ranges. The decision threshold should be defined within these ranges.

2.3.4 GNSS Antenna Interface Characteristics

Table 11: GNSS properties

Parameter	Conditions	Min.	Typical	Max.	Unit	
Frequency	GPS	1574.4	1575.42	1576.4	MHz	
	GLONASS	1597.5	1602	1605.9		
Tracking Sensitivity	Open sky (active antenna or LNA): GPS		-159		dBm	
	Open sky (active antenna or LAN): GLONASS		-158			
	Open sky (passive antenna): GPS		-156			
	Open sky (passive antenna): GLONASS		-156			
Acquisition Sensitivity	Open sky (active antenna or LNA): GPS		-147		dBm	
	Open sky (active antenna or LNA): GLONASS		-146			
	Open sky (passive antenna): GPS		-145			
	Open sky (passive antenna): GLONASS		-144			
Time-to-First-Fix (TTFF) ¹	Warm (average at -130dBm)		28		s	
	Cold (average at -130dBm)		32		s	

^{1.} Open sky environment

Note: For PLSx3-W modules, if GNSS works together with LTE Band13 in the field, to avoid Band13 second harmonic interfere GNSS sensitivity in the worst LET network condition, please design the GNSS antenna at least 20dB decoupling with LTE main antenna and use the extra LNA for GNSS.

2.4 Sample Application

Figure 25 shows a typical example of how to integrate a PLSx3 module with an application. Usage of the various host interfaces depends on the desired features of the application.

Because of the very low power consumption design, current flowing from any other source into the module circuit must be avoided, for example reverse current from high state external control lines. Therefore, the controlling application must be designed to prevent reverse current flow. Otherwise there is the risk of undefined states of the module during startup and shutdown or even of damaging the module.

Because of the high RF field density inside the module, it cannot be guaranteed that no self interference might occur, depending on frequency and the applications grounding concept. The potential interferers may be minimized by placing small capacitors (47pF) at suspected lines (e.g. RXD0, VDDLP, and ON).

While developing SMT applications it is strongly recommended to provide test points for certain signals, i.e., lines to and from the module - for debug and/or test purposes. The SMT application should allow for an easy access to these signals. For details on how to implement test points see [4].

The EMC measures are best practice recommendations. In fact, an adequate EMC strategy for an individual application is very much determined by the overall layout and, especially, the position of components. For example, mounting the internal acoustic transducers directly on the PCB eliminates the need to use the ferrite beads shown in the sample schematic.

Disclaimer

No warranty, either stated or implied, is provided on the sample schematic diagram shown in Figure 25 and the information detailed in this section. As functionality and compliance with national regulations depend to a great amount on the used electronic components and the individual application layout manufacturers are required to ensure adequate design and operating safeguards for their products using PLSx3 modules.

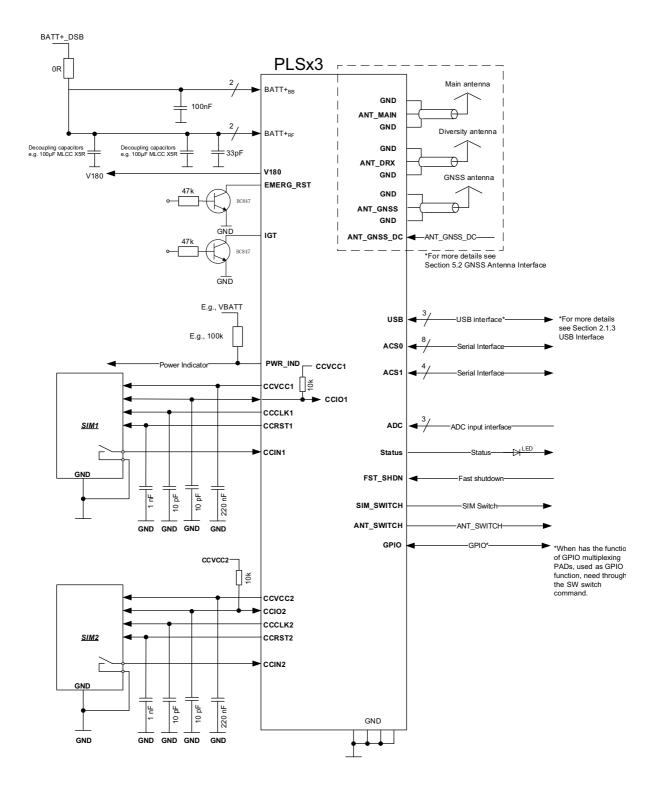


Figure 25: Schematic diagram of PLSx3 sample application

3 Operating Characteristics

3.1 Operating Modes

The table below briefly summarizes the various operating modes referred to throughout the document.

Table 12: Overview of operating modes

Mode	Function	
Normal operation	GSM / GPRS / UMTS / HSPA / LTE SLEEP	Power saving set automatically when no call is in progress and the USB connection is suspended by host or not present and no active communication via ASC0.
	GSM / GPRS / UMTS / HSPA / LTE IDLE	Power saving disabled or an USB connection not suspended, but no call in progress.
	GSM TALK/ GSM DATA	Connection between two subscribers is in progress. Power consumption depends on the GSM network coverage and several connection settings (e.g. DTX off/on, FR/EFR/HR, hopping sequences and antenna connection). The following applies when power is to be measured in TALK_GSM mode: DTX off, FR and no frequency hopping.
	GPRS DATA	GPRS data transfer in progress. Power consumption depends on network settings (e.g. power control level), uplink / downlink data rates and GPRS configuration (e.g. used multislot settings).
	EGPRS DATA	EGPRS data transfer in progress. Power consumption depends on network settings (e.g. power control level), uplink / downlink data rates and EGPRS configuration (e.g. used multislot settings).
	UMTS TALK/ UMTS DATA	UMTS data transfer in progress. Power consumption depends on network settings (e.g. TPC Pattern) and data transfer rate.
	HSPA DATA	HSPA data transfer in progress. Power consumption depends on network settings (e.g. TPC Pattern) and data transfer rate.
	LTE TALK/ LTE DATA	LTE data transfer in progress. Power consumption depends on network settings (e.g. TPC Pattern) and data transfer rate.
Power Down	Normal shutdown after sending the power down command. Only a voltage regulator is active for powering the RTC. Software is not active. Interfaces are not accessible. Operating voltage remains applied.	
Airplane mode	Airplane mode shuts down the radio part of the module, causes the module to log off from the network and disables all AT commands whose execution requires a radio connection. Airplane mode can be controlled by AT command (see [1]).	

3.2 Power Up/Power Down Scenarios

In general, be sure not to turn on PLSx3 while it is beyond the safety limits of voltage and temperature stated in Section 2.1.2.1. PLSx3 immediately switches off after having started and detected these inappropriate conditions. In extreme cases this can cause permanent damage to the module.

3.2.1 Turn on PLSx3

After the operating voltage BATT+ is applied, PLSx3 can be switched on by means of the IGT signal.

The IGT signal turns on the module if the module is in power down mode. The IGT signal is low level triggered. The module starts in the operating mode with a continuous low level signal. It is recommended to pull the IGT sinal to GND directly when powering on. The low pulse width must be longer than 300ms as shown in Figure 26.

When a automatic power-on is needed, IGT can always be connected to GND.

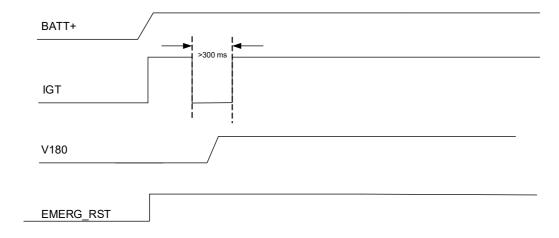


Figure 26: IGT timing

3.2.2 Restart PLSx3

To switch the module off the following procedures may be used:

- Software controlled restart procedure: Software controlled by sending an AT command over the serial application interface. See Section 3.2.2.1.
- Hardware controlled restart procedure: Hardware controlled by using the EMERG_RST line (see Section 3.2.2.2).

3.2.2.1 Restart PLSx3 Using Restart Command

After startup PLSx3 can be re-started using the AT+CFUN command. For details see [1]

3.2.2.2 Restart PLSx3 Using EMERG_RST

The EMERG_RST signal is internally connected to the baseband processor. A low level >200ms sets the processor and all signals to the reset states, and thus restart the module.

Please note that if the EMERG_RST signal is not released, i.e., changed from low to high, after a restart, the module will be repeatedly restarted. When the timer of the EMERG_RST signal is more than 8000ms, the module will be switched off directly.

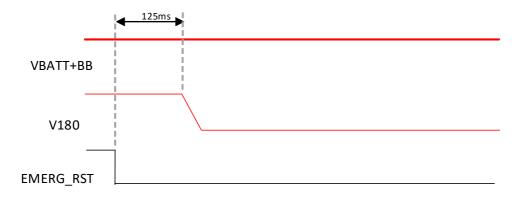


Figure 27: Emergency reset timing

It is strongly recommended to control this EMERG_RST line with an open collector transistor or an open drain field-effect transistor.

Caution: Use the EMERG_RST line only when, due to serious problems, the software is not responding for more than 5 seconds. Pulling the EMERG_RST line causes the loss of all information stored in the volatile memory, and the information in non-volatile may not stored in a consistency way. Furthermore, the module may get damaged permanently under some unlike circumstances. Therefore, this procedure is intended only for use in case of emergency, e.g. if PLSx3 does not respond, if reset or shutdown via AT command fails.

Caution: The EMERG_RST will still work when the module is powered off (e.g. via AT^SMSO) but VBATT+ supply remains. In case EMERG_RST is in use, please keep it high to avoid unexpected restart in the power-off state.

3.2.3 Signal States after Startup

Table 13 lists the states each interface signal passes through during reset phase and the first firmware initialization. For further firmware startup initializations the values may differ because of different GPIO line configurations.

After the reset state has been reached the firmware initialization state begins. The firmware initialization is completed as soon as the ASC0 interface lines CTS0, DSR0 and RING0 have turned low (see Section 2.1.4 and Section 2.1.5). Now, the module is ready to receive and transmit data.

Table 13: Pull-up and Pull-down Values

Signal name	Reset state	First start up configuration
RXD0	PD	O/H
TXD0	PD	PD
RTS0		
CTS0	PD	O/L
STATUS/GPIO5	PD	PD
DSR0/GPIO3	PD	O/L
DCD0/GPIO2	PD	O/H
RING0/GPIO24	PD	O/H
RXD1/GPIO16	PD	O/H
TXD1/GPIO17	PD	PD
RTS1/GPIO18	PD	PD
CTS1/GPIO19	O/H	O/H
GPIO6-8	PD	PD
GPIO11-13	PD	PD
GPIO14-15		
GPIO25	I	I
GPIO20	PD	PD
GPIO21	PD	O/H
SIM_SWITCH/GPIO26	PD	PD
FAST_SHDN/GPIO4	PD	PD

Note: the values above are stored as non-volatile, any changes of the value will take effect after next power-cycle and remain effective before any change happens again.

Abbreviations used in above Table 13:

L = Low level	O = Output
H = High level	OD = Open Drain
T = Tristate	PD = Pull down, 200µA at 1.9V
I = Input	PU = Pull up, -240µA at 0V

3.2.4 Turn off PLSx3

To switch the module off the following procedures may be used:

- Software controlled shutdown procedure: Software controlled by sending an AT command over the serial application interface. See Section 3.2.4.1
- Hardware controlled shutdown procedure: Hardware controlled by setting the FST_SHDN line to low. See Section 2.1.9.3
- Automatic shutdown (software controlled): See Section 3.2.5
 - Take effect if PLSx3 board temperature exceeds a critical limit, or if
 - Undervoltage or overvlotage is detected.

3.2.4.1 Switch off PLSx3 Using AT Command

The best and safest approach to powering down the module is to issue the AT^SMSO command. This procedure lets the module log off from the network and allows the software to enter into a secure state and to save data before disconnecting the power supply. The shutdown procedure will be an active process for about 2 seconds (depending on environmental conditions such as network states) until the module switches off.

A low level of the V180 signal as well as the URC "^SHUTDOWN" indicate that the switch off procedure has completed and the module has entered the Power Down mode.

3.2.5 Automatic Shutdown

Automatic shutdown takes effect if the following event occurs:

- PLSx3 board is exceeding the critical limits of overtemperature or undertemperature (see Section 3.2.5.1)
- Undervoltage or overvoltage is detected (see Section 3.2.5.2 and Section 3.2.5.3)

The automatic shutdown procedure is equivalent to the power-down initiated with an AT command, i.e. PLSx3 logs off from the network and the software enters a secure state avoiding loss of data.

3.2.5.1 Thermal Shutdown

The board temperature is constantly monitored by an internal NTC resistor located on the PCB. The values detected by the NTC resistor are measured directly on the board and therefore, are not fully identical with the ambient temperature.

Each time the board temperature goes out of range or back to normal, PLSx3 instantly displays an alert (if enabled).

- URCs indicating the level "1" or "-1" allow the user to take appropriate precautions, such as protecting the module from exposure to extreme conditions. The presentation of the URCs depends on the settings selected with the AT^SCTM write command (for details see [1]): AT^SCTM=1: Presentation of URCs is always enabled.
 AT^SCTM=0 (default): Presentation of URCs is enabled during the 2 minute guard period after start-up of PLSx3. After expiry of the 2 minute guard period, the presentation of URCs will be disabled, i.e. no URCs with alert levels "1" or "-1" will be generated.
- URCs indicating the level "2" or "-2" are instantly followed by an orderly shutdown after 5 seconds unless the temperature returns to a valid operating level ("1", "0", "-1") or the shutdown ability was disabled with AT^SCFG, "MEopMode/ShutdownOnCritTemp",<sdoct>. The presentation of these URCs is always enabled, i.e. they will be output even though the factory setting AT^SCTM=0 was never changed.

The maximum temperature ratings are stated in Section 3.6. Refer to Table 14 for the associated URCs.

Table 14: Temperature associated URCs

Sending temperature alert (2min after PLSx3 start-up, otherwise only if URC presentation enabled)		
^SCTM_B: 1	Board close to overtemperature limit.	
^SCTM_B: -1	Board close to undertemperature limit.	
^SCTM_B: 0	Board back to non-critical temperature range.	
Automatic shutdown (URC appears no matter whether or not presentation was enabled)		
^SCTM_B: 2	B: 2 Alert: Board equal or beyond overtemperature limit. PLSx3 switches off.	
^SCTM_B: -2	Alert: Board equal or below undertemperature limit. PLSx3 switches off.	

3.2.5.2 Undervoltage Shutdown

The undervoltage shutdown threshold is the specified minimum supply voltage VBATT+ given in Table 3. When the average supply voltage measured by PLSx3 approaches the undervoltage shutdown threshold (i.e., 0.05V offset) the module will send the following URC:

^SBC: Undervoltage Shutdown

If the undervoltage persists the module will send the URC several times before switching off automatically.

This type of URC does not need to be activated by the user. It will be output automatically when fault conditions occur.

3.2.5.3 Overvoltage Shutdown

The overvoltage shutdown threshold is the specified maximum supply voltage VBATT+ given in Table 3. When the supply voltage approaches the overvoltage shutdown threshold, the module will send the following URC:

^SBC: Overvoltage Shutdown

The overvoltage warning is sent only once before the module is close to the overvoltage shutdown threshold again.

This type of URC does not need to be activated by the user. It will be output automatically when fault conditions occur.

Keep in mind that several PLSx3 components are directly linked to BATT+ and, therefore, the supply voltage remains applied at major parts of PLSx3, even if the module is switched off. Especially the power amplifier is very sensitive to high voltage and might even be destroyed

3.2.5.4 Deferred Shutdown at Extreme Temperature Condition

In the following cases, automatic shutdown will be deferred if a critical temperature limit is exceeded:

- While an emergency call is in progress.
- During a two minute guard period after power-up. This guard period has been introduced in order to allow for the user to make an emergency call. The start of any one of these calls extends the guard period until the end of the call. Any other network activity may be terminated by shutdown upon expiry of the guard time.

While in a "deferred shutdown" situation, PLSx3 continues to measure the temperature and to deliver alert messages, but deactivates the shutdown functionality. Once the 2 minute guard period is expired or the call is terminated, full temperature control will be resumed. If the temperature is still out of range, PLSx3 switches off immediately (without another alert message).

Caution: Automatic shutdown is a safety feature intended to prevent damage to the module. Extended usage of the deferred shutdown facilities provided may result in damage to the module, and possibly other severe consequences.

3.3 Power Saving

PLSx3 is able to reduce its functionality to a minimum (during the so-called SLEEP mode and SUSPEND mode) in order to minimize its current consumption. The following sections explain the module's network dependent power saving behavior. The power saving behavior is further configurable by AT command:

- When all serial interfaces (i.e. ASC0, and ASC1) are idle, the module can enter SLEEP mode by additional configuration settings (i.e. AT^SPOW=2.3000,255).
- AT^SCFG= "MEopMode/ExpectDTR": Power saving will take effect only if there is no transmission data pending on any of the module's USB ports. The expect DTR AT command ensures that data becoming pending on any USB port before an external application has signaled its readiness to receive the data is discarded. By default this behavior is enabled for all available USB CDC ACM.
- Using the AT command AT^SCFG="Radio/OutputPowerReduction" it is possible for the module in GPRS multislot scenarios to reduce its output power according to 3GPP 45.005 section.

3.3.1 Power Saving while Attached to GSM Networks

The power saving possibilities while attached to a GSM network depend on the paging timing cycle of the base station. The duration of a power saving interval can be calculated using the following formula:

t = 4.615 ms (TDMA frame duration) * 51 (number of frames) * DRX value.

DRX (Discontinuous Reception) is a value from 2 to 9, resulting in paging intervals between 0.47 and 2.12 seconds. The DRX value of the base station is assigned by the GSM network operator.

Now, a paging timing cycle consists of the actual fixed length paging plus a variable length pause before the next paging. In the pauses between listening to paging messages, the module resumes power saving, as shown in Figure 28.

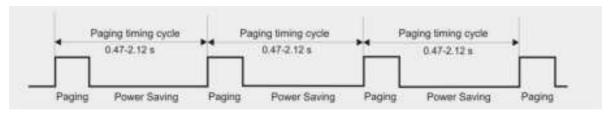


Figure 28: Power saving and paging in GSM networks

The varying pauses explain the different potential for power saving. The longer the pause the less power is consumed.

Generally, power saving depends on the module's application scenario and may differ from the above mentioned normal operation. The power saving interval may be shorter than 0.47 seconds or longer than 2.12 seconds.

3.3.2 Power Saving while Attached to WCDMA Networks

The power saving possibilities while attached to a WCDMA network depend on the paging timing cycle of the base station.

During normal WCDMA operation, i.e., the module is connected to a WCDMA network, the duration of a power saving period varies. It may be calculated using the following formula:

 $t = 2^{DRX \text{ value}} * 10 \text{ ms}$ (WCDMA frame duration).

DRX (Discontinuous Reception) in WCDMA networks is a value between 6 and 9, thus resulting in power saving intervals between 0.64 and 5.12 seconds. The DRX value of the base station is assigned by the WCDMA network operator.

Now, a paging timing cycle consists of the actual fixed length paging plus a variable length pause before the next paging. In the pauses between listening to paging messages, the module resumes power saving, as shown in Figure 29.

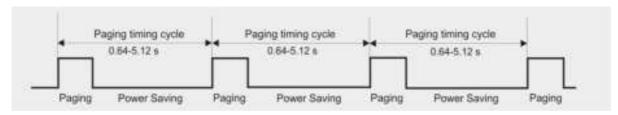


Figure 29: Power saving and paging in WCDMA networks

The varying pauses explain the different potential for power saving. The longer the pause the less power is consumed.

Generally, power saving depends on the module's application scenario and may differ from the above mentioned normal operation. The power saving interval may be shorter than 0.64 seconds or longer than 5.12 seconds.

3.3.3 Power Saving while Attached to LTE Networks

The power saving possibilities while attached to an LTE network depend on the paging timing cycle of the base station.

During normal LTE operation, i.e., the module is connected to an LTE network, the duration of a power saving period varies. It may be calculated using the following formula:

t = DRX Cycle Value * 10 ms

DRX cycle value in LTE networks is any of the four values: 32, 64, 128 and 256, thus resulting in power saving intervals between 0.32 and 2.56 seconds. The DRX cycle value of the base station is assigned by the LTE network operator.

Now, a paging timing cycle consists of the actual fixed length paging plus a variable length pause before the next paging. In the pauses between listening to paging messages, the module resumes power saving, as shown in Figure 30.



Figure 30: Power saving and paging in LTE networks

The varying pauses explain the different potential for power saving. The longer the pause the less power is consumed.

Generally, power saving depends on the module's application scenario and may differ from the above mentioned normal operation. The power saving interval may be shorter than 0.32 seconds or longer than 2.56 seconds.

3.3.4 Wake-up via RTS0

RTS0 can be used to wake up PLSx3 from SLEEP mode configured with AT^SPOW. Assertion of RTS0 (i.e., toggle from inactive high to active low) serves as wake up event, thus allowing an external application to almost immediately terminate power saving. After RTS0 assertion, the CTS0 line signals module wake up, i.e., readiness of the AT command interface. It is therefore recommended to enable RTS/CTS flow control (default setting).

Figure 31 shows the described RTS0 wake up mechanism.

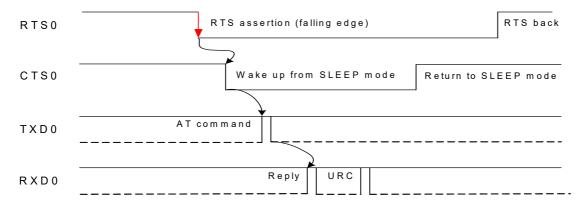


Figure 31: Wake-up via RTS0

3.4 Power Supply

PLSx3 needs to be connected to a power supply at the SMT application interface - 4 lines BATT+, and GND. There are two separate voltage domains for BATT+:

- BATT+_{BB} with two lines for the general power management.
- BATT+_{RF} with two lines for the RF.

Please note that throughout the document BATT+ refers to both voltage domains and power supply lines - $BATT+_{BB}$ and $BATT+_{RF}$.

The main power supply from an external application has to be a single voltage source and has to be expanded to sub paths (star structure). BATT+ $_{RF}$ must be decoupled by application with low ESR capacitors($\geq 2x100\mu F$ MLCC X5R@BATT+ $_{RF}$) as close as possible to LGA pads. Figure 32 shows a sample circuit for decoupling capacitors for BATT+.

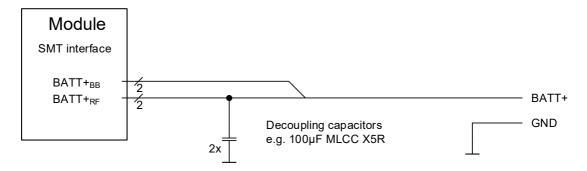


Figure 32: Decoupling capacitor(s) for BATT+

The power supply of PLSx3 must be able to provide the peak current during the uplink transmission.

All the key functions for supplying power to the device are handled by the power management section of the analog controller. This IC provides the following features:

- Stabilizes the supply voltages for the baseband using low drop linear voltage regulators and DC-DC step down switching regulators.
- Switches the module's power voltages for the power-up and -down procedures.
- SIM switch to provide SIM power supply.

3.4.1 Power Supply Ratings

The tables in this section assemble various voltage supply and current consumption ratings of the module.

Table 15: Supply Ratings

	Description	Conditions	Min	Тур	Max	Unit
BATT+	Supply voltage	Normal Range (Directly measured at Module. Voltage must stay within the min/max values, including voltage drop, ripple, spikes.) The module shall work with supply voltages between 3.0 and 4.5V as normal voltage range.	3.0	3.8	4.5	V
	Maximum allowed voltage drop during transmit burst	Normal condition, power control level for Pout max			400	mV
	Voltage ripple	Normal condition, power control level for Pout max @ f ≤ 250 kHz @ f > 250 kHz			120 90	${\rm mV_{pp} \atop mV_{pp}}$

Table 16: Current Consumption Ratings -GSM¹

	Description	Conditions		Typical rating (-W)	Unit
I _{BATT+} ²	GSM SLEEP	SLEEP ³ @ DRX=9	USB disconnected	2.365	mA
(i.e., sum of BATT+ _{BB} and	State supply current	(no communication via UART)	USB suspended	2.690	mA
BATT+ _{RF})		SLEEP ³ @ DRX=5	USB disconnected	2.534	mA
		(no communication via UART)	USB suspended	2.839	mA
		SLEEP ³ @ DRX=2	USB disconnected	2.992	mA
		(no communication via UART)	USB suspended	3.296	mA
	GSM IDLE ⁴ State	IDLE @ DRX=2	USB disconnected	12.083	mA
	supply current	(UART active, but no communication)	USB active	27.706	mA
	Average GSM850 supply current ⁵	GPRS Data transfer GSM850;	ROPR=8 (max. reduction)	315	mA
		PCL=5; 1Tx/4Rx	ROPR=4 (no reduction)	315	mA
		GPRS Data transfer GSM850; PCL=5; 2Tx/3Rx	ROPR=8 (max. reduction)	455	mA
			ROPR=4 (no reduction)	566	mA
		GPRS Data transfer GSM850; PCL=5; 4Tx/1Rx	ROPR=8 (max. reduction)	631	mA
			ROPR=4 (no reduction)	1049	mA
		EDGE Data transfer GSM850; PCL=5; 1Tx/4Rx	ROPR=8 (max. reduction)	203	mA
			ROPR=4 (no reduction)	206	mA
		EDGE Data transfer GSM850;	ROPR=8 (max. reduction)	303	mA
		PCL=5; 2Tx/3Rx	ROPR=4 (no reduction)	349	mA
		EDGE Data transfer GSM850;	ROPR=8 (max. reduction)	486	mA
		PCL=5; 4Tx/1Rx	ROPR=4 (no reduction)	615	mA

Table 16: Current Consumption Ratings -GSM¹

	Description	Conditions		Typical rating (-W)	Unit
I _{BATT+} ²	₃and '' ′	GPRS Data transfer GSM900;	ROPR=8 (max. reduction)	307	mA
(i.e., sum of BATT+ _{BB} and BATT+ _{RF})		PCL=5; 1Tx/4Rx	ROPR=4 (no reduction)	307	mA
		GPRS Data transfer GSM900;	ROPR=8 (max. reduction)	446	mA
	PCL=5; 2Tx/3Rx	ROPR=4 (no reduction)	554	mA	
		GPRS Data transfer GSM900; PCL=5; 4Tx/1Rx	ROPR=8 (max. reduction)	638	mA
			ROPR=4 (no reduction)	1009	mA
		EDGE Data transfer GSM900; PCL=5; 1Tx/4Rx	ROPR=8 (max. reduction)	198	mA
			ROPR=4 (no reduction)	201	mA
		EDGE Data transfer GSM900;	ROPR=8 (max. reduction)	301	mA
		PCL=5; 2Tx/3Rx	ROPR=4 (no reduction)	340	mA
		EDGE Data transfer GSM900;	ROPR=8 (max. reduction)	487	mA
		PCL=5; 4Tx/1Rx	ROPR=4 (no reduction)	607	mA

Table 16: Current Consumption Ratings -GSM¹

	Description	Conditions		Typical rating (-W)	Unit
I _{BATT+} ²	_B and '' ′	GSM1800 GSM1800; PCL=0;		209	mA
(i.e., sum of BATT+ _{BB} and BATT+ _{RF})		1Tx/4Rx	ROPR=4 (no reduction)	209	mA
		GPRS Data transfer GSM1800; PCL=0;	ROPR=8 (max. reduction)	295	mA
	2Tx/3Rx	ROPR=4 (no reduction)	359	mA	
		GPRS Data transfer GSM1800; PCL=0; 4Tx/1Rx	ROPR=8 (max. reduction)	433	mA
			ROPR=4 (no reduction)	640	mA
		EDGE Data transfer GSM1800; PCL=0; 1Tx/4Rx	ROPR=8 (max. reduction)	163	mA
			ROPR=4 (no reduction)	163	mA
		EDGE Data transfer GSM1800; PCL=0;	ROPR=8 (max. reduction)	250	mA
		2Tx/3Rx	ROPR=4 (no reduction)	269	mA
		EDGE Data transfer GSM1800; PCL=0;	ROPR=8 (max. reduction)	420	mA
		4Tx/1Rx	ROPR=4 (no reduction)	471	mA

Table 16: Current Consumption Ratings -GSM1

	Description	Conditions		Typical rating (-W)	Unit
I _{BATT+} ²	Average GSM1900	M1900 GSM1900; PCL=0;		210	mA
(i.e., sum of BATT+ _{BB} and BATT+ _{RF})	supply current ⁵	1Tx/4Rx	ROPR=4 (no reduction)	208	mA
		GPRS Data transfer GSM1900; PCL=0;	ROPR=8 (max. reduction)	295	mA
		2Tx/3Rx	ROPR=4 (no reduction)	358	mA
		GPRS Data transfer GSM1900; PCL=0;	ROPR=8 (max. reduction)	433	mA
	4Tx/1Rx	ROPR=4 (no reduction)	643	mA	
	EDGE Data transfer GSM1900; PCL=0; 1Tx/4Rx	ROPR=8 (max. reduction)	162	mA	
		11x/4Rx	ROPR=4 (no reduction)	163	mA
		EDGE Data transfer GSM1900; PCL=0; 2Tx/3Rx	ROPR=8 (max. reduction)	249	mA
			ROPR=4 (no reduction)	272	mA
		EDGE Data transfer GSM1900; PCL=0; 4Tx/1Rx	ROPR=8 (max. reduction)	417	mA
			ROPR=4 (no reduction)	476	mA
	Peak current during GSM	GPRS Data transfer GS 1Rx @ 50Ω	SM850; PCL=5; 1Tx/	2.3	Α
	transmit burst ⁵	GPRS Data transfer GS 1Rx @ 50Ω	PRS Data transfer GSM900; PCL=5; 1Tx/ Rx @ 50Ω		Α
		GPRS Data transfer DCS1800; PCL=0; 1Tx/1Rx @ 50Ω		1.4	Α
		GPRS Data transfer PCS1900; PCL=0; 1Tx/1Rx @ 50Ω		1.4	А
		GPRS Data transfer GMS850; PCL=5; 1Tx/1Rx @ total mismatch		2.7	Α
1		GPRS Data transfer GMS900; PCL=5; 1Tx/1Rx @ total mismatch		2.8	Α
		GPRS Data transfer DC 1Rx @ total mismatch		1.7	Α
		GPRS Data transfer DC 1Rx @ total mismatch		1.8	Α

^{1.} Note: Current consumption ratings are based on measurements done in a laboratory test environment, and deviations may occur from the given typical ratings. Under real life conditions however, with e.g., varying network quality, location changes, or changing supply currents, the deviations from these typical ratings may be even bigger, and will have to be taken into account for actual power supply solutions. For more details on power supply design see [3].

^{2.} With an impedance of $\rm Z_{LOAD}\text{=}50\Omega$ at the antenna pad. Measured at 25°C and 3.8V.

- 3. Measurements start 6 minutes after switching ON the module, averaging times: SLEEP mode 3 minutes, transfer modes 1.5 minutes Communication tester settings:no neighbor cells, no cell reselection etc., RMC (Reference Measurement Channel) SLEEP mode is enabled via AT command AT^SPOW=2, 1000, 3
- 4. The power save mode is disabled via AT command AT^SPOW=1,0,0
- 5. The communication tester settings of Channel: Mid Channel

Table 17: Current Consumption Ratings - UMTS¹

	Description	Conditions		Typical rating (-W)	Typical rating (-X)	Unit
I _{BATT+} ²	UMTS SLEEP State supply current	SLEEP ³ @ DRX=9 (no communication	USB disconnected	2.336		mA
(i.e., sum of BATT+BB	ÍT+ _{BB}	via UART)	USB suspended	2.6	698	mA
BATT+ _{RF})		SLEEP ³ @ DRX=8 (no communication via UART)	USB disconnected	2.4	131	mA
		,	USB suspended	2.7	778	mA
		SLEEP ³ @ DRX=6 (no communication via UART)	USB disconnected	2.864		mA
	Via		USB suspended	3.196		mA
	UMTS IDLE ⁴ State supply current IDLE @ DRX=6 (UART active, but no communication)	USB disconnected	11.785		mA	
		Communications	USB active	26.	138	mA
	UMTS average	UMTS Data transfer Band I		560		mA
	supply current ⁵	UMTS Data transfer B	and II	550	606	mA
		UMTS Data transfer B	and III	502		mA
		UMTS Data transfer B	and IV	570	713	mA
	UMTS Data transfer Band V		and V	516	542	mA
		UMTS Data transfer B		516		mA
		UMTS Data transfer B		534		mA
		UMTS Data transfer B	and XIX	507		mA

- 1. Note: Current consumption ratings are based on measurements done in a laboratory test environment, and deviations may occur from the given typical ratings. Under real life conditions however, with e.g., varying network quality, location changes, or changing supply currents, the deviations from these typical ratings may be even bigger, and will have to be taken into account for actual power supply solutions. For more details on power supply design see [3].
- 2. With an impedance of Z_{LOAD} =50 Ω at the antenna pad. Measured at 25°C and 3.8V.
- Measurements start 6 minutes after switching ON the module, averaging times: SLEEP mode – 3 minutes, transfer modes – 1.5 minutes Communication tester settings:no neighbor cells, no cell reselection etc., RMC (Reference Measurement Channel)
- SLEEP mode is enabled via AT command AT^SPOW=2, 1000, 3
- 4. The power save mode is disabled via AT command AT^SPOW=1,0,0
- 5. The communication tester settings of Channel: Mid Channel

The value is based on the latest test result and may have update in the future releases.

Table 18: Current Consumption Ratings - LTE¹

	Description	Conditions		Typical rating (-W)	Typical rating (-X)	Unit
I _{BATT+} ²	LTE SLEEP	SLEEP ³ @ "Paging Cycles =	USB disconnected	2.4	196	mA
(i.e.,	State supply current	256" (no communication via UART)	USB suspended	2.7	793	mA
sum of BATT+		SLEEP ³ @ "Paging Cycles =	USB disconnected	2.7	740	mA
_{BB} and BATT+		128" (no communication via UART)	USB suspended	3.0	098	mA
RF)		SLEEP ³ @ "Paging Cycles =	USB disconnected	3.2	291	mA
		64" (no communication via UART)	USB suspended	3.6	623	mA
		SLEEP ³ @ "Paging Cycles =	USB disconnected	4.3	399	mA
		32" (no communication via UART)	USB suspended	4.7	717	mA
	LTE IDLE ⁴	IDLE (USB disconnected)		12.	991	mA
	State supply current	IDLE (USB active)		28.	465	mA
	LTE average	LTE Data transfer Band 1		604		mA
	supply cur- rent ⁵	LTE Data transfer Band 2		622	596	mA
		LTE Data transfer Band 3		557		mA
		LTE Data transfer Band 4		570	674	mA
		LTE Data transfer Band 5		564	535	mA
		LTE Data transfer Band 7(-W)		758		mA
		LTE Data transfer Band 8		658		mA
		LTE Data transfer Band 12		669	565	mA
		LTE Data transfer Band 13		641	579	mA
		LTE Data transfer Band 14			520	mA
		LTE Data transfer Band 17		640		mA
		LTE Data transfer Band 18		520		mA
		LTE Data transfer Band 19		561		mA
		LTE Data transfer Band 20		634		mA
		LTE Data transfer Band 25			600	mA
		LTE Data transfer Band 26		636	529	mA
		LTE Data transfer Band 28		630		mA
		LTE Data transfer Band 38		397		mA
		LTE Data transfer Band 40		405		mA
		LTE Data transfer Band 41		399		mA
		LTE Data transfer Band 66		650	675	mA
		LTE Data transfer Band 71			594	mA

- 1. Note: Current consumption ratings are based on measurements done in a laboratory test environment, and deviations may occur from the given typical ratings. Under real life conditions however, with e.g., varying network quality, location changes, or changing supply currents, the deviations from these typical ratings may be even bigger, and will have to be taken into account for actual power supply solutions. For more details on power supply design see [3].
- 2. With an impedance of $\rm Z_{LOAD}{=}50\Omega$ at the antenna pad. Measured at 25°C and 3.8V.
- 3. Measurements start 6 minutes after switching ON the module, averaging times: SLEEP mode 3 minutes, transfer modes 1.5 minutes Communication tester settings:no neighbor cells, no cell reselection etc., RMC (Reference Measurement Channel)

SLEEP mode is enabled via AT command AT^SPOW=2, 1000, 3

- 4. The power save mode is disabled via AT command AT^SPOW=1,0,0
- 5. Communication tester setting:

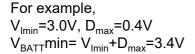
Channel: Mid Channel Channel Bandwidth: 5MHz

Number of Resource Blocks: 25 (DL), 1 (UL), RB position: Low

Modulation: QPSK

3.4.2 Minimizing Power Losses

If the module supports GSM, when designing the power supply for your application, please pay specific attention to power losses. Ensure that the input voltage V_{BATT+} , never drops below 3.0V on the PLSx3 board, not even in a transmit burst where current consumption can rise to typical peaks. Any voltage drops that may occur in a transmit burst should not exceed 400mV to ensure the expected RF performance.



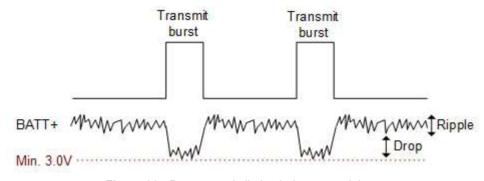


Figure 33: Power supply limits during transmit burst

3.4.3 Monitoring Power Supply by AT Command

To monitor the supply voltage, you can use the AT^SBV command which returns the current value of the supply voltage using AT interface.

3.5 Operating Temperatures

Table 19: Board Temperature

Parameter	Min	Тур	Max	Unit
Operating temperature range	-30		+85	°C
Restricted temperature range ¹	-40		+95	°C
Automatic shutdown ² Temperature measured on PLSx3 board	<-40		+95	°C

- 1. Restricted operation allows normal mode data transmissions for limited time until automatic thermal shutdown takes effect. Within the restricted temperature range (outside the operating temperature range) the specified electrical characteristics may be in- or decreased.
- 2. Due to temperature measurement uncertainty, a tolerance on the stated shutdown thresholds may occur. The possible deviation is in the range of ±2 °C at the over temperature limit.

Note: Within the specified operating temperature ranges the board temperature may vary to a great extent depending on operating mode, used frequency band, radio output power and current supply voltage.

3.6 Electrostatic Discharge

The module is not protected against Electrostatic Discharge (ESD) in general. Consequently, it is subject to ESD handling precautions that typically apply to ESD sensitive components. Proper ESD handling and packaging procedures must be applied throughout the processing, handling and operation of any application that incorporates a PLSx3 module.

An example for an enhanced ESD protection for the SIM interface is given in Section 2.1.6.1.

PLSx3 has been tested according to the following standards. Electrostatic values can be gathered from the following table.

Table 20: Electrostatic values

Specification/Requirement	Contact discharge	Air discharge			
ANSI/ESDA/JEDEC JS-001-2017 (Human Body Model)					
All LGA pads	±1.0kV (HBM)	n.a.			
JS-002-2018 (Charged Device	Model)				
All LGA pads	±250V (CDM)	n.a.			
ETSI EN 301 489-1/7	ETSI EN 301 489-1/7				
BATT+	±4kV	±8kV			
Antenna pads	±4kV	±8kV			

3.7 Reliability Characteristics

The test conditions stated below are an extract of the complete test specifications.

Table 21: Summary of reliability test conditions

Type of test	Conditions	Standard
Vibration	Frequency range: 10-20Hz; acceleration: 5g Frequency range: 20-500Hz; acceleration: 20g Duration: 20h per axis; 3 axes	DIN IEC 60068-2-6 ¹
Shock half-sinus	Acceleration: 500g Shock duration: 1ms 1 shock per axis 6 positions (± x, y and z)	DIN IEC 60068-2-27
Dry heat	Temperature: +70 ±2°C Test duration: 16h Humidity in the test chamber: < 50%	EN 60068-2-2 Bb ETS 300 019-2-7
Temperature change (shock)	Low temperature: -40°C ±2°C High temperature: +85°C ±2°C Changeover time: < 30s (dual chamber system) Test duration: 1h Number of repetitions: 100	DIN IEC 60068-2-14 Na ETS 300 019-2-7
Damp heat cyclic	High temperature: +55°C ±2°C Low temperature: +25°C ±2°C Humidity: 93% ±3% Number of repetitions: 6 Test duration: 12h + 12h	DIN IEC 60068-2-30 Db ETS 300 019-2-5
Cold (constant exposure)	Temperature: -40 ±2°C Test duration: 16h	DIN IEC 60068-2-1

^{1.} For reliability tests in the frequency range 20-500Hz the Standard's acceleration reference value was increased to 20g.

4 Mechanical Dimensions, Mounting and Packaging

4.1 Mechanical Dimensions of PLSx3

Figure 34 shows the top and bottom view of PLSx3 and provides an overview of the board's mechanical dimensions. For further details see Figure 35.

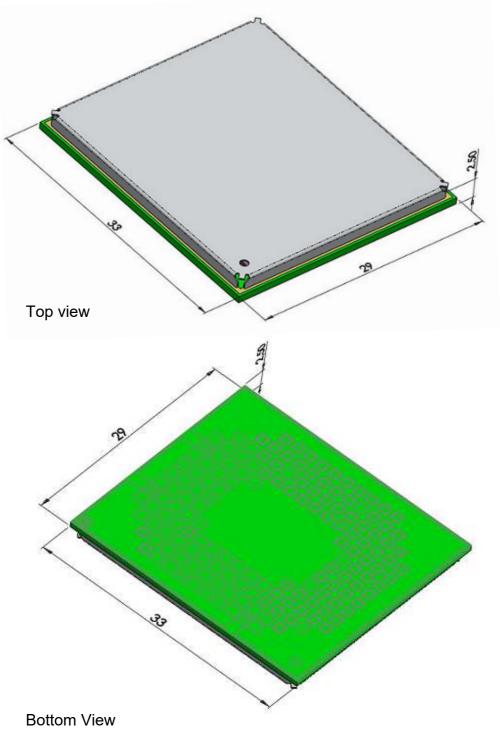
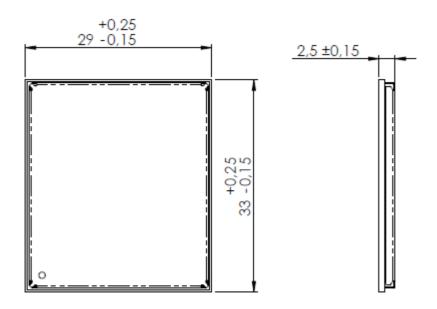


Figure 34: PLSx3- top and bottom view



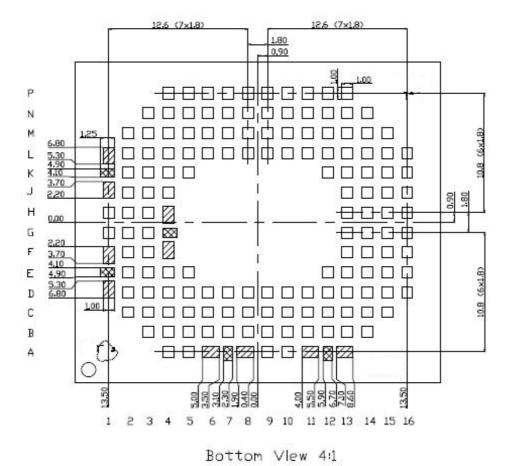


Figure 35: Dimensions of PLSx3 (all dimensions in mm)

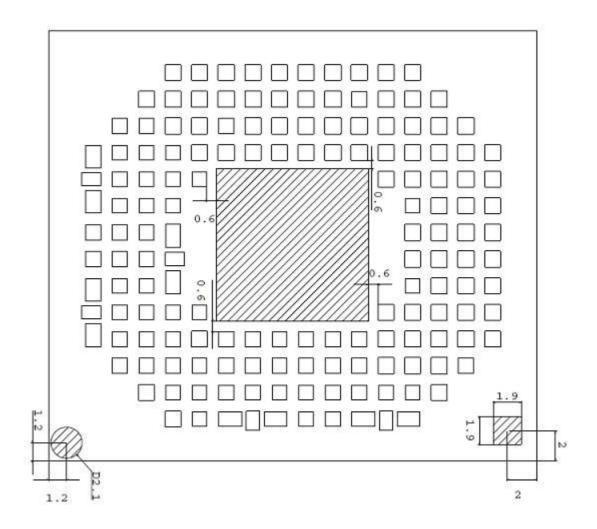


Figure 36: Dimensions of PLSx3 (keepout area recommended)

4.2 Mounting PLSx3 onto the Application Platform

This section describes how to mount PLSx3 onto the PCBs, including land pattern and stencil design, board-level characterization, soldering conditions, durability and mechanical handling.

Note: To avoid short circuits between signal tracks on an external application's PCB and various markings at the bottom side of the module, it is recommended not to route the signal tracks on the top layer of an external PCB directly under the module, or at least to ensure that signal track routes are sufficiently covered with solder resist.

Note: Do not place external components or devices that might cause any pressure on the module's shielding. See [4] and [5] for further details of thermal and integration guidance.

4.2.1 SMT PCB Assembly

4.2.1.1 Land Pattern and Stencil

The land pattern and stencil design as shown below is based on Thales characterizations for lead-free solder paste on a four-layer test PCB and a 110 respectively 150 micron thick stencil.

The land pattern given in Figure 37 reflects the module's pad layout, including signal pads and ground pads (for pad assignment see Section 2.1.1).

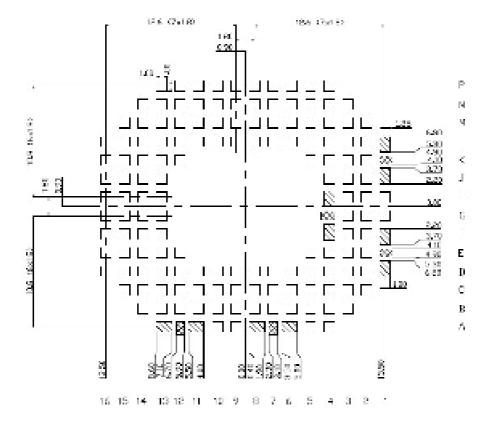


Figure 37: Land pattern (top view)

The stencil designs illustrated in Figure 38 and Figure 39 are recommended by Thales as a re-

sult of extensive tests with Thales Daisy Chain modules.

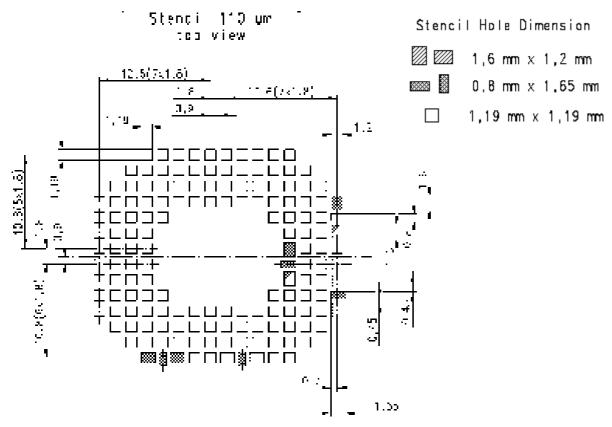


Figure 38: Recommended design for 110 micron thick stencil (top view)

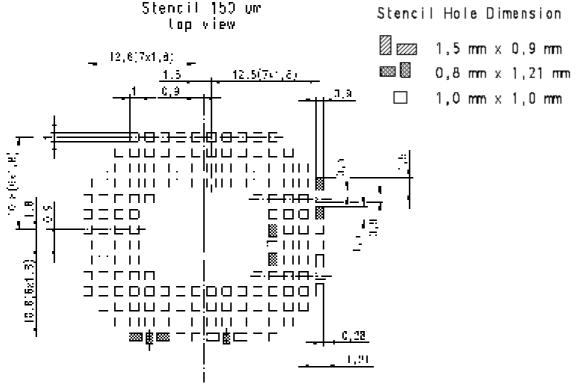


Figure 39: Recommended design for 150 micron thick stencil (top view)

4.2.1.2 Board Level Characterization

Board level characterization issues should also be taken into account if devising an SMT process.

Characterization tests should attempt to optimize the SMT process with regard to board level reliability. This can be done by performing the following physical tests on sample boards: Peel test, bend test, tensile pull test, drop shock test and temperature cycling.

It is recommended to characterize land patterns before an actual PCB production, taking individual processes, materials, equipment, stencil design, and reflow profile into account. For land and stencil pattern design recommendations see also Section 4.2.1.1. Optimizing the solder stencil pattern design and print process is necessary to ensure print uniformity, to decrease solder voids, and to increase board level reliability.

Generally, solder paste manufacturer recommendations for screen printing process parameters and reflow profile conditions should be followed. Maximum ratings are described in Section 4.2.3.

4.2.2 Moisture Sensitivity Level

PLSx3 comprises components that are susceptible to damage induced by absorbed moisture.

Thales's PLSx3 module complies with the latest revision of the IPC/JEDEC J-STD-020 Standard for moisture sensitive surface mount devices and is classified as MSL 4.

For additional moisture sensitivity level (MSL) related information see Section 4.2.4 and Section 4.3.2.

4.2.3 Soldering Conditions and Temperature

4.2.3.1 Reflow Profile

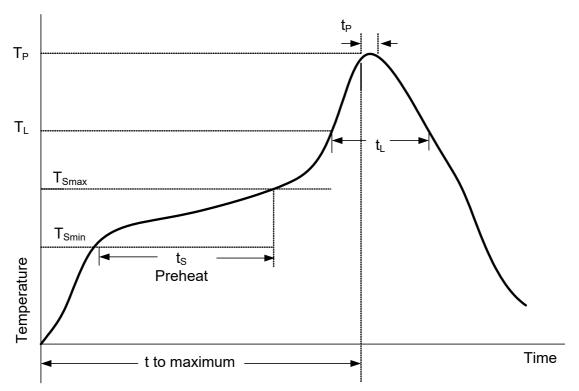


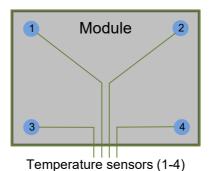
Figure 40: Reflow Profile

Table 22: Reflow temperature ratings¹

Profile Feature	Pb-Free Assembly
Preheat & Soak Temperature Minimum (T_{Smin}) Temperature Maximum (T_{Smax}) Time $(t_{Smin}$ to $t_{Smax})$ (t_{S})	150°C 200°C 60-120 seconds
Average ramp up rate (T _L to T _P)	3K/second max. ²
Liquidous temperature (T _L) Time at liquidous (t _L)	217°C 50-90 seconds
Peak package body temperature (T _P)	245°C ±5°C
Time (t_P) within 5 °C of the peak package body temperature (T_P)	30 seconds max.
Limited ramp-down rate (Tp -200°C) Average ramp-down rate from 200°C	1.5-2.5K/second max. ^{2 3} 3K-6k/second max. ²
Time 25°C to maximum temperature	8 minutes max.

^{1.} Please note that the reflow profile features and ratings listed above are based on the joint industry standard IPC/JEDEC J-STD-020E.1, and are as such meant as a general guideline. For more information on reflow profile and their optimization please refer to [4].

2. Temperatures measured on shielding at each corner.See also [4]. During critical ramp-down phase (Tp -200°C) temperature differences between sensors 1,2,3,4 should be as low as possible.



3. Lowest ramp-down rate achievable is also dependent on reflow oven type and settings used. Use the lowest possible ramp down rate from Tp - 200°C. See also [4].

4.2.3.2 Maximum Temperature and Duration

The following limits are recommended for the SMT board-level soldering process to attach the module:

- A maximum module temperature of 245°C. This specifies the temperature as measured at the module's top side.
- A maximum duration of 30 seconds at this temperature.
- Ramp-down rate from T_P to 200°C should be controlled in order to reduce thermally induced stress during the solder solidification phase (see Table 22 - limited ramp-down rate). Therefore, a cool-down step in the oven's temperature program between 200°C and 180°C should be considered.

Please note that while the solder paste manufacturers' recommendations for best temperature and duration for solder reflow should generally be followed, the limits listed above must not be exceeded.

PLSx3 is specified for one soldering cycle only. Once PLSx3 is removed from the application, the module will very likely be destroyed and cannot be soldered onto another application.

4.2.4 Durability and Mechanical Handling

4.2.4.1 Storage Conditions

PLSx3 modules, as delivered in tape and reel carriers, must be stored in sealed, moisture barrier anti-static bags. The conditions stated below are only valid for modules in their original packed state in weather protected, non-temperature-controlled storage locations. Normal storage time under these conditions is 12 months maximum.

Table 23: Storage conditions

Туре	Condition	Unit	Reference
Air temperature: Low High	-25 +40	°C	IPC/JEDEC J-STD-033A
Humidity relative: Low High	10 90 at 40°C	%	IPC/JEDEC J-STD-033A
Air pressure: Low High	70 106	kPa	IEC TR 60271-3-1: 1K4 IEC TR 60271-3-1: 1K4
Movement of surrounding air	1.0	m/s	IEC TR 60271-3-1: 1K4
Water: rain, dripping, icing and frosting	Not allowed		
Radiation: Solar Heat	1120 600	W/m ²	ETS 300 019-2-1: T1.2, IEC 60068-2-2 Bb ETS 300 019-2-1: T1.2, IEC 60068-2-2 Bb
Chemically active substances	Not recommended		IEC TR 60271-3-1: 1C1L
Mechanically active substances	Not recommended		IEC TR 60271-3-1: 1S1
Vibration sinusoidal: Displacement Acceleration Frequency range	1.5 5 2-9 9-200	mm m/s ² Hz	IEC TR 60271-3-1: 1M2
Shocks: Shock spectrum Duration Acceleration	semi-sinusoidal 1 50	ms m/s ²	IEC 60068-2-27 Ea

4.2.4.2 Processing Life

PLSx3 must be soldered to an application within 72 hours after opening the moisture barrier bag (MBB) it was stored in.

As specified in the IPC/JEDEC J-STD-033 Standard, the manufacturing site processing the modules should have ambient temperatures below 30°C and a relative humidity below 60%.

4.2.4.3 **Baking**

Baking conditions are specified on the moisture sensitivity label attached to each MBB (see Figure 46 for details):

- It is *not necessary* to bake PLSx3, if the conditions specified in Section 4.2.4.1 and Section 4.2.4.2 were not exceeded.
- It is *necessary* to bake PLSx3, if any condition specified in Section 4.2.4.1 and Section 4.2.4.2 was exceeded.

If baking is necessary, the modules must be put into trays that can be baked to at least 125°C. Devices should not be baked in tape and reel carriers at any temperature.

4.2.4.4 Electrostatic Discharge

Electrostatic discharge (ESD) may lead to irreversable damage for the module. It is therefore advisable to develop measures and methods to counter ESD and to use these to control the electrostatic environment at manufacturing sites.

Please refer to Section 3.6 for further information on electrostatic discharge.

4.3 Packaging

4.3.1 Tape and Reel

The single-feed tape carrier for PLSx3 is illustrated in Figure 41. The figure also shows the proper part orientation. The tape width is 44mm and the PLSx3 modules are placed on the tape with a 40mm pitch. The reels are 330mm in diameter with 100mm hubs. Each reel contains 400 modules.

4.3.1.1 Orientation

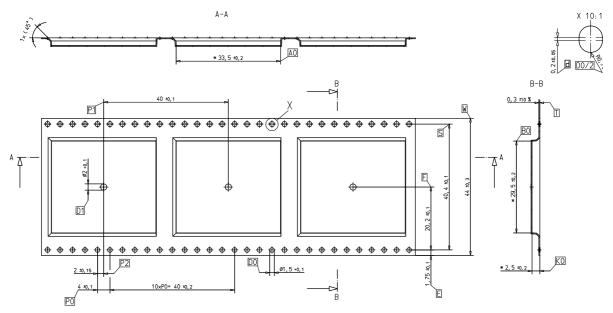


Figure 41: Carrier tape

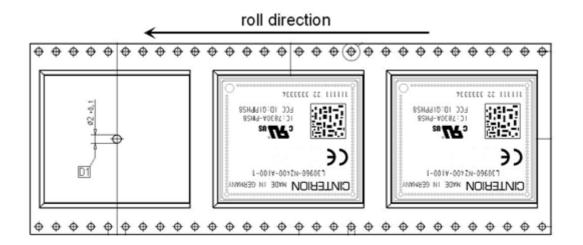


Figure 42: Reel direction

4.3.1.2 Barcode Label

A barcode label provides detailed information on the tape and its contents. It is attached to the reel.

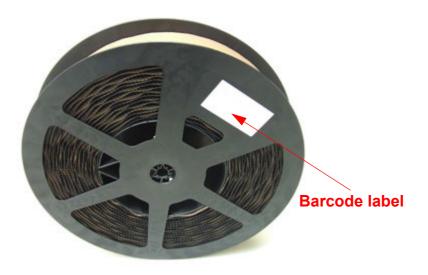


Figure 43: Barcode label on tape reel

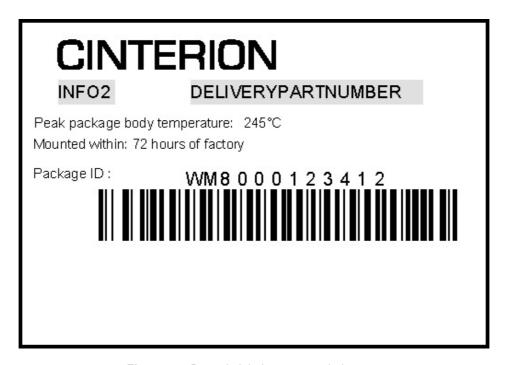


Figure 44: Barcode label on tape reel - layout

Variables on the label are explained in Table 24.

4.3.2 Shipping Materials

PLSx3 is distributed in tape and reel carriers. The tape and reel carriers used to distribute PLSx3 are packed as described below, including the following required shipping materials:

- · Moisture barrier bag, including desiccant and humidity indicator card
- Transportation box

4.3.2.1 Moisture Barrier Bag

The tape reels are stored inside a moisture barrier bag (MBB), together with a humidity indicator card and desiccant pouches - see Figure 45. The bag is ESD protected and delimits moisture transmission. It is vacuum-sealed and should be handled carefully to avoid puncturing or tearing. The bag protects the PLSx3 modules from moisture exposure. It should not be opened until the devices are ready to be soldered onto the application.

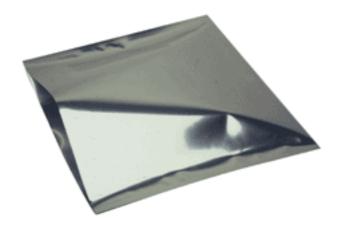




Figure 45: Moisture barrier bag (MBB) with imprint

The label shown in Figure 46 summarizes requirements regarding moisture sensitivity, including shelf life and baking requirements. It is attached to the outside of the moisture barrier bag.

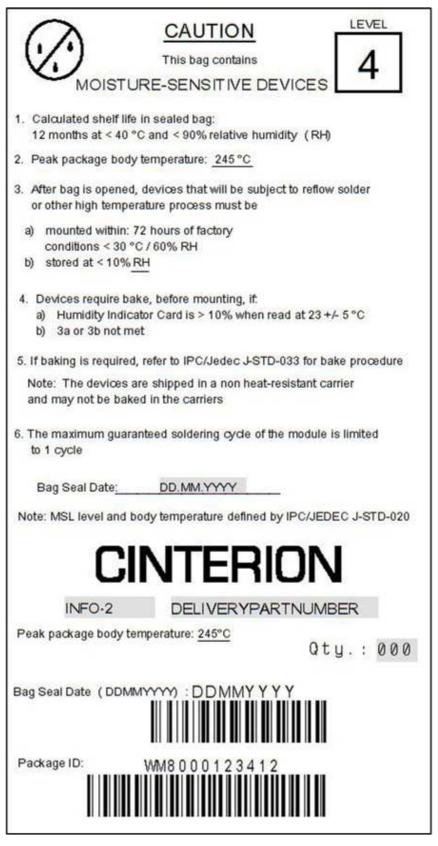


Figure 46: Moisture Sensitivity Label

MBBs contain one or more desiccant pouches to absorb moisture that may be in the bag. The humidity indicator card described below should be used to determine whether the enclosed components have absorbed an excessive amount of moisture.

The desiccant pouches should not be baked or reused once removed from the MBB.

The humidity indicator card is a moisture indicator and is included in the MBB to show the approximate relative humidity level within the bag. Sample humidity cards are shown in Figure 47. If the components have been exposed to moisture above the recommended limits, the units will have to be rebaked.

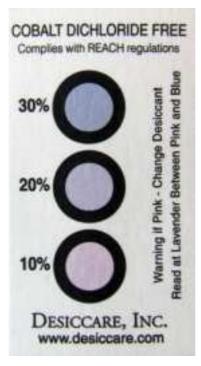


Figure 47: Humidity Indicator Card - HIC

A baking is required if the humidity indicator inside the bag indicates 10% RH or more.

4.3.2.2 Transportation Box

Tape and reel carriers are distributed in a box, marked with a barcode label for identification purposes. A box contains two reels with 400 (TBD for -X variant) modules each.

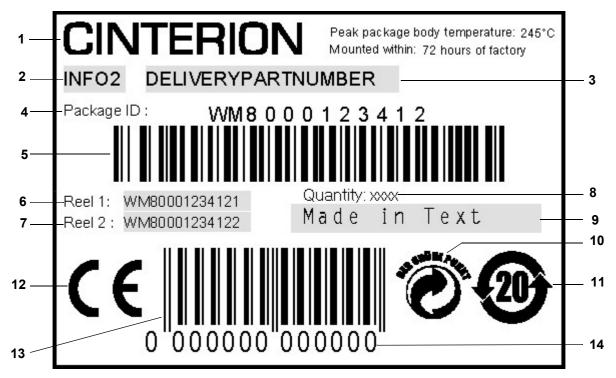


Figure 48: Sample of VP box label

Table 24: VP Box label information

No.	Information
1	Cinterion logo
2	Product name
3	Product ordering number
4	Package ID number of VP box (format may vary depending on the product)
5	Package ID barcode (Code 128)
6	Package ID Reel 1 (format may vary depending on the product)
7	Package ID Reel 2 (format may vary depending on the product)
8	Quantity of the modules inside the VP box (max. 1000 pcs)
9	Country of production
10	Der Grüne Punkt (Green Dot) symbol
11	Chinese RoHS symbol (see Table 35)
12	CE logo (CE mark on VP box label is present only for modules with CE imprinted on the shielding)
13	European Article Number (EAN-13) barcode
14	European Article Number, consists of 13 digits (EAN-13)

5 Regulatory and Type Approval Information

5.1 Directives and Standards

PLSx3 is designed to comply with the directives and standards listed below.

It is the responsibility of the application manufacturer to ensure compliance of the final product with all provisions of the applicable directives and standards as well as with the technical specifications provided in the "PLSx3 Hardware Interface Description".

Table 25: Directives

2014/53/EU	Directive of the European Parliament and of the council of 16 April 2014 on the harmonization of the laws of the Member States relating to the making available on the market of radio equipment and repealing Directive 1999/05/EC. The product is labeled with the CE conformity mark.
2002/95/EC (RoHS 1) 2011/65/EC (RoHS 2)	Directive of the European Parliament and of the Council of 27 January 2003 (and revised on 8 June 2011) on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS)
1907/2006/EC (REACH)	Regulation (EC) No 1907/2006 of the European Parliament and of the Council of 18 December 2006 concerning the Registration, Evaluation, Authorization and Restriction of Chemicals (REACH), establishing a European Chemicals Agency, amending Directive 1999/45/EC and repealing Council Regulation (EEC) No 793/93 and Commission Regulation (EC) No 1488/94 as well as Council Directive 76/769/EEC and Commission Directive 91/155/EEC, 93/67/EC and 2000/21/EC. Cinterion® module comply with the REACH regulation that specifies a content of less than 0.1% per substance mentioned in the SVHC candidate list (Release 16.06.2014)

Table 26: Standards of North American type approval

CFR Title 47	Code of Federal Regulations, Part 22, Part 24; US Equipment Authorization FCC
OET Bulletin 65 (Edition 97-01)	Evaluating Compliance with FCC Guidelines for Human Exposure to Radio frequency Electromagnetic Fields
UL 62368-1	Audio/video, information and communication technology equipment - Part1: Safety requirements (for details see Section 5.1.1)
NAPRD.03 V6.01	Overview of PCS Type certification review board Mobile Equipment Type Certification and IMEI control PCS Type Certification Review board (PTCRB)
RSS132 (Issue2) RSS133 (Issue5)	Canadian Standard

^{1.} Manufacturers of applications which can be used in the US shall ensure that their applications have a PTCRB approval. For this purpose they can refer to the PTCRB approval of the respective module.

Table 27: Standards of European type approval

3GPP TS 51.010-1	Digital cellular telecommunications system (Release 7); Mobile Station (MS) conformance specification;
GCF-CC V3.79	Global Certification Forum - Certification Criteria
ETSI EN 301 511 V12.5.1	Global System for Mobile communications (GSM); Mobile Stations (MS) equipment; Harmonized Standard covering the essential requirements of article 3.2 of Directive 2014/53/EU
ETSI EN 301 908-01 V13.1.1	IMT cellular networks; Harmonized Standard covering the essential requirements of article 3.2 of the Directive 2014/53/EU; Part 1: Introduction and common requirements
ETSI EN 301 908-02 V11.1.2	IMT cellular networks; Harmonized Standard covering the essential requirements of article 3.2 of the Directive 2014/53/EU; Part 2: CDMA Direct Spread (UTRA FDD) User Equipment (UE)
ETSI EN 301 489-52 V1.1.0	Electromagnetic Compatibility (EMC) standard for radio equipment and services; Part 52: Specific conditions for Cellular Communication Mobile and portable (UE) radio and ancillary equipment; Harmonized Standard covering the essential requirements of article 3.1(b) of Directive 2014/53/EU
ETSI EN 301 908-13 V13.1.1	IMT cellular networks; Harmonized Standard covering the essential requirements of article 3.2 of the Directive 2014/53/EU; Part 13: evolved Universal Terrestrial Radio Access (E-UTRA) User Equipment (UE).
Draft ETSI EN 301 489- 01 V2.2.3	Electromagnetic Compatibility (EMC) standard for radio equipment and services; Part 1: Common technical requirements; Harmonized Standard covering the essential requirements of article 3.1(b) of Directive 2014/53/EU and the essential requirements of article 6 of Directive 2014/30/EU
ETSI EN 301489-19 V2.1.0	ElectroMagnetic Compatibility (EMC) standard for radio equipment and services; Part 19: Specific conditions for Receive Only Mobile Earth Stations (ROMES) operating in the 1,5 GHz band providing data communications and GNSS receivers operating in the RNSS band (ROGNSS) providing positioning, navigation, and timing data; Harmonised Standard covering the essential requirements of article 3.1(b) of Directive 2014/53/EU
ETSI EN 303 413 V1.1.1	Satellite Earth Stations and Systems (SES); Global Navigation Satellite System (GNSS) receivers; Radio equipment operating in the 1 164 MHz to 1 300 MHz and 1 559 MHz to 1 610 MHz frequency bands; Harmonised Standard covering the essential requirements of article 3.2 of Directive 2014/53/EU
IEC 62368-1 (EN 62368-1, UL 62368- 1)	Audio/video, information and communication technology equipment - Part 1: Safety requirements (for details see Section 5.1.1)

Table 28: Standards (Statutory Instruments) for UK

S.I. 2019/696 Part 3 Regulation 32 Schedule 29	The Product Safety and Metrology etc. (Amendment etc.) (EU Exit) Regulations 2019, Amendment of the Radio Equipment Regulations 2017 and related amendments. The product is labeled with the UK conformity mark
S.I. 2012/3032	Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment Regulations 2012
S.I. 2016 No. 1101 Chapter 1, clause 6-1 a	Electrical Equipment (Safety) Regulations 2016
S.I. 2016 No. 1091 Chapter 1, clause 6-1 b	The Electromagnetic Compatibility Regulations 2016
S.I. 2017 No. 1206 Chapter 1, clause 6-2	The Radio Equipment Regulations 2017

Table 29: Requirements of quality

IEC 60068	Environmental testing
DIN EN 60529	IP codes
EN 62311:2008	Assessment of electronic and electrical equipment related to human exposure restrictions for electromagnetic fields (0 Hz - 300 GHz)

Table 30: Standards of the Ministry of Information Industry of the People's Republic of China

SJ/T 11363-2006	"Requirements for Concentration Limits for Certain Hazardous Substances in Electronic Information Products" (2006-06).
SJ/T 11364-2006	"Marking for Control of Pollution Caused by Electronic Information Products" (2006-06).
	According to the "Chinese Administration on the Control of Pollution caused by Electronic Information Products" (ACPEIP) the EPUP, i.e., Environmental Protection Use Period, of this product is 20 years as per the symbol shown here, unless otherwise marked. The EPUP is valid only as long as the product is operated within the operating limits described in the Thales Hardware Interface Description.
	Please see Table 31 for an overview of toxic or hazardous substances or elements that might be contained in product parts in concentrations above the limits defined by SJ/T 11363-2006.

Table 31: Toxic or hazardous substances or elements with defined concentration limits

部件名称	有毒有害物质或元素 Hazardous substances					
Name of the part	铅 (Pb)	汞 (Hg)	镉 (Cd)	六价铬 (Cr(VI))	多溴联苯 (PBB)	多溴二苯醚 (PBDE)
金属部件 (Metal Parts)	0	0	0	0	0	0
电路模块 (Circuit Modules)	х	0	0	0	0	0
电缆及电缆组件 (Cables and Cable Assemblies)	0	0	0	0	0	0
塑料和聚合物部件 (Plastic and Polymeric parts)	0	0	0	0	0	0

0:

表示该有毒有害物质在该部件所有均质材料中的含量均在SJ/T11363-2006 标准规定的限量要求以下。 Indicates that this toxic or hazardous substance contained in all of the homogeneous materials for this part is below the limit requirement in SJ/T11363-2006.

X:

表示该有毒有害物质至少在该部件的某一均质材料中的含量超出SJ/T11363-2006标准规定的限量要求。 Indicates that this toxic or hazardous substance contained in at least one of the homogeneous materials used for this part *might exceed* the limit requirement in SJ/T11363-2006.

5.1.1 IEC 62368-1 Classification

With respect to the safety requirements for audio/video, information and communication technology equipment defined by the hazard based product safety standard for ICT and AV equipment - i.e., IEC-62368-1 (EN 62368-1, UL 62368-1) - Cinterion® modules are classified as shown below:

Standalone operation of the modules is not possible. Modules will always be incorporated in an external application (Customer Product).

Customer understands and is responsible that the product incorporating the Cinterion® module must be designed to be compliant with IEC-62368-1 (EN 62368-1, UL 62368-1) to ensure protection against hazards and injuries. When operating the Cinterion® module the external application (Customer Product) must provide safeguards not to exceed the power limits given by classification to Power Source Class 1 (15 Watts) under normal operating conditions, abnormal conditions, or in the presence of a single fault. When using a battery power supply the external application must provide safeguards not to exceed the limits defined by PS-1, as well. The external application (Customer Product) must take measures to limit the power, the voltage or the current, respectively, if required, and must provide safeguards to protect ordinary persons against pain or injury caused by the voltage/current.

In case of a usage of the Cinterion[®] module not in accordance with the specifications or in single fault condition the external application (Customer Product) must be capable to withstand levels according to ES-1 / PS-1 also on all ports that are initially intended for signalling or audio, e.g., USB, RS-232, GPIOs, SPI, earphone and microphone interfaces.

In addition, the external application (Customer Product) must be designed in a way to distribute thermal energy generated by the intended operation of the Cinterion® module. In case of high temperature operation, the external application must provide safeguards to protect ordinary persons against pain or injury caused by the heat.

Table 32: IEC 62368-1 Classification

Source of Energy	Class	Limits
Electrical energy source	ES-1	The Cinterion® modules contain no electrical energy source - especially no battery. The electrical components and circuits have to be externally power supplied: DC either smaller 60 V Or less than 2 mA AC up to 1kHz smaller 30 V-rms or 42.4 V peak AC above 100kHz smaller 70 V rms
Power Source (potential ignition source causing fire)	PS-1	Power source provided by the external application must not exceed 15W, even under worst case and any single fault condition defined by IEC-62368-1: Section 6.2.2.3.

Table 32: IEC 62368-1 Classification

Source of Energy	Class	Limits
Hazardous Substances, Chemical reaction	-	Under regular conditions, the Cinterion® modules does not contain any chemically reactive substances, and no chemical energy source, especially no battery. Module is compliant with RoHS and REACH.
		In very rare cases however - under abnormal conditions 9i.e. wrong supply voltage, burned module) or in the presence of single electrical component faults (i.e. shortcut) - health hazardous substances might be released if the worst comes to the worst.
Kinetic / mechanical energy source	MS-1	The Cinterion® modules have no sharp edges and corners, no moving parts, no loosing, exploding or imploding parts. The mass is well below 1kg.
Thermal energy source	TS-2	Under normal operating conditions, abnormal operating conditions or single fault conditions the temperature does not exceed +100°C on the metal surface (shielding)
Thermal energy source Note: Valid only for Cinterion® modules with dimensions larger than 50mm and operating board temperatures higher than +80°C.	TS-3	Special safeguards required.
Radiated energy source	RS-1	The Cinterion® module does not contain a radiant energy source, any lasers, lamps, LEDs, X-Ray emitting components or acoustic couplers.

5.2 SAR requirements specific to portable mobiles

Mobile phones, PDAs or other portable transmitters and receivers incorporating a GSM/UMTS module must be in accordance with the guidelines for human exposure to radio frequency energy. This requires the Specific Absorption Rate (SAR) of portable PLSx3 based applications to be evaluated and approved for compliance with national and/or international regulations.

Since the SAR value varies significantly with the individual product design manufacturers are advised to submit their product for approval if designed for portable use. For European/US/Australian-markets the relevant directives are mentioned below. The manufacturer of the end device is in the responsibility to provide clear installation and operating instructions for the user, including the minimum separation distance required to maintain compliance with SAR and/or RF field strength limits, as well as any special usage conditions required to do so, such as a required accessory, the proper orientation of the device, the max antenna gain for detachable antennas, or other relevant criteria. It is the responsibility of the manufacturer of the final product to verify whether or not further standards, recommendations or directives are in force outside these areas.

Products intended for sale on US markets

ES 59005/ANSI C95.1 Considerations for evaluation of human exposure to Electromagnetic Fields (EMFs) from Mobile Telecommunication Equipment (MTE) in the frequency range 30MHz - 6GHz

Products intended for sale on European markets

EN 50360 Product standard to demonstrate the compliance of mobile phones with

the basic restrictions related to human exposure to electromagnetic

fields (300MHz - 3GHz)

EN 62311:2008 Assessment of electronic and electrical equipment related to human

expo-sure restrictions for electromagnetic fields (0 Hz - 300 GHz)

Please note that SAR requirements are specific only for portable devices and not for mobile devices as defined below:

- Portable device:
 - A portable device is defined as a transmitting device designed to be used so that the radiating structure(s) of the device is/are within 20 centimeters of the body of the user.
- Mobile device:
 - A mobile device is defined as a transmitting device designed to be used in other than fixed locations and to generally be used in such a way that a separation distance of at least 20 centimeters is normally maintained between the transmitter's radiating structure(s) and the body of the user or nearby persons. In this context, the term "fixed location" means that the device is physically secured at one location and is not able to be easily moved to another location.

5.3 Reference Equipment for Type Approval

The Thales reference setup submitted to type approve PLSx3 (including a special approval adapter for the DSB75) is shown in the following figure¹:

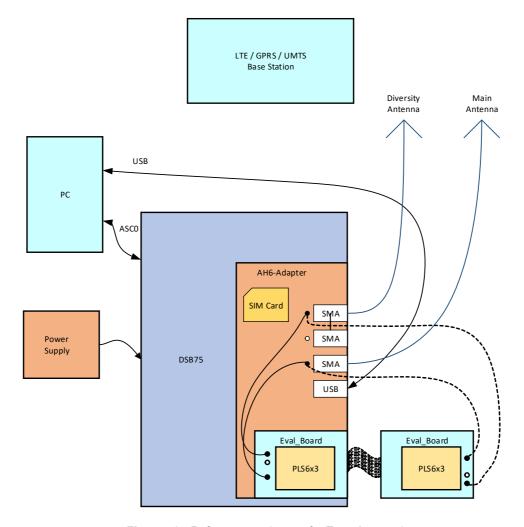


Figure 49: Reference equipment for Type Approval

^{1.} For RF performance tests a mini-SMT/U.FL to SMA adapter with attached 6dB coaxial attenuator is chosen to connect the evaluation module directly to the GSM/UMTS test equipment instead of employing the SMA antenna connectors on the PLSx3-DSB75 adapter as shown in Figure 49. The following products are recommended:

Hirose SMA-Jack/U.FL-Plug conversion adapter HRMJ-U.FLP(40)

⁽for details see http://www.hirose-connectors.com/ or http://www.farnell.com/

Aeroflex Weinschel Fixed Coaxial Attenuator Model 3T/4T

⁽for details see http://www.aeroflex.com/ams/weinschel/pdfiles/wmod3&4T.pdf)

5.4 Compliance with FCC and ISED Rules and Regulations

The Equipment Authorization Certification for the Thales reference application described in Section 5.3 will be registered under the following identifiers:

FCC Identifier: QIPPLS63-W

Industry Canada Certification Number: 7830A-PLS63W Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS83-W

Industry Canada Certification Number: 7830A-PLS83W Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS63-X

Industry Canada Certification Number: 7830A-PLS63X Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS83-X

Industry Canada Certification Number: 7830A-PLS83X Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS63-X2

Industry Canada Certification Number: 7830A-PLS63X2 Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS83-X2

Industry Canada Certification Number: 7830A-PLS83X2 Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS63-X3

Industry Canada Certification Number: 7830A-PLS63X3
Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS83-X3

Industry Canada Certification Number: 7830A-PLS83X3
Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS63-X4

Industry Canada Certification Number: 7830A-PLS63X4 Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPPLS83-X4

Industry Canada Certification Number: 7830A-PLS83X4 Granted to THALES DIS AIS Deutschland GmbH

Manufacturers of mobile or fixed devices incorporating PLSx3 modules are authorized to use the FCC Grants and ISED Certificates of the PLSx3 modules for their own final products according to the conditions referenced in these documents. In this case, an FCC/IC label of the module shall be visible from the outside, or the host device shall bear a second label stating "Contains FCC ID: QIPPLS63-W", "Contains FCC ID: QIPPLS83-W", "Contains FCC ID: QIPPLS63-X", "Contains FCC ID: QIPPLS63-X2", "Contains FCC ID: QIPPLS63-X2", "Contains FCC ID: QIPPLS83-X3", "Contains FCC ID

tains FCC ID: QIPPLS63-X4", "Contains FCC ID: QIPPLS83-X4", and accordingly "Contains IC: 7830A-PLS63W", "Contains IC: 7830A-PLS63X", "Contains IC: 7830A-PLS63X", "Contains IC: 7830A-PLS63X2", "Contains IC: 7830A-PLS63X2", "Contains IC: 7830A-PLS63X3", "Contains IC: 7830A-PLS63X4", "Contains IC: 7830A-PLS63X4", "Contains IC: 7830A-PLS83X4".

The integration is limited to fixed or mobile categorized host devices, where a separation distance between the antenna and any person of min. 20cm can be assured during normal operating conditions.

For mobile and fixed operation configuration the antenna gain, including cable loss, must not exceed the limits listed in the following Table 33 and Table for FCC and ISED.

 Table 33:
 Antenna gain limits for FCC and ISED (for W and EP variants)

Operation band	FCC limit	ISED limit	Unit
Maximum gain in GSM/GPRS 850	8.60	5.30	dBi
Maximum gain in PCS 1900	10.20	10.20	dBi
Maximum gain in WCDMA Band 2	8.01	8.01	dBi
Maximum gain in WCDMA Band 4	5.00	5.00	dBi
Maximum gain in WCDMA Band 5	9.40	6.10	dBi
Maximum gain in LTE Band 2	8.01	8.01	dBi
Maximum gain in LTE Band 4	5.00	5.00	dBi
Maximum gain in LTE Band 5	9.40	6.10	dBi
Maximum gain in LTE Band 7	8.01	8.01	dBi
Maximum gain in LTE Band 8	9.70	-	dBi
Maximum gain in LTE Band 12	8.70	5.61	dBi
Maximum gain in LTE Band 13	9.16	5.93	dBi
Maximum gain in LTE Band 26	9.30	6.10	dBi
Maximum gain in LTE Band 38	8.01	8.01	dBi
Maximum gain in LTE Band 41	8.01	8.01	dBi
Maximum gain in LTE Band 66	5.00	5.00	dBi

Table 34: Antenna gain limits for FCC and ISED (for X, X2, X3, X4 variants)

Operation band	FCC limit	ISED limit	Unit
Maximum gain in WCDMA Band 2	8.01	8.01	dBi
Maximum gain in WCDMA Band 4	5.00	5.00	dBi
Maximum gain in WCDMA Band 5	9.40	6.10	dBi
Maximum gain in LTE Band 2	8.01	8.01	dBi
Maximum gain in LTE Band 4	5.00	5.00	dBi
Maximum gain in LTE Band 5	9.40	6.10	dBi
Maximum gain in LTE Band 12	8.70	5.61	dBi

Table 34: Antenna gain limits for FCC and ISED (for X, X2, X3, X4 variants)

Operation band	FCC limit	ISED limit	Unit
Maximum gain in LTE Band 13	9.16	5.93	dBi
Maximum gain in LTE Band 14	9.23	N.A.	dBi
Maximum gain in LTE Band 25	8.01	8.01	dBi
Maximum gain in LTE Band 26	9.30	6.10	dBi
Maximum gain in LTE Band 66	5.00	5.00	dBi
Maximum gain in LTE Band 71	8.48	5.45	dBi

IMPORTANT:

Manufacturers of portable applications incorporating PLSx3 modules are required to have their final product certified and apply for their own FCC Grant and ISED Certificate related to the specific portable mobile. This is mandatory to meet the SAR requirements for portable mobiles (see Section Table 31: for detail).

Changes or modifications not expressly approved by the party responsible for compliance could void the user's authority to operate the equipment.

Note: This equipment has been tested and found to comply with the limits for a Class B digital device, pursuant to part 15 of the FCC Rules and with ISED license-exempt RSS standard(s). These limits are designed to provide reasonable protection against harmful interference in a residential installation. This equipment generates, uses and can radiate radio frequency energy and, if not installed and used in accordance with the instructions, may cause harmful interference to radio communications. However, there is no guarantee that interference will not occur in a particular installation. If this equipment does cause harmful interference to radio or television reception, which can be determined by turning the equipment off and on, the user is encouraged to try to correct the interference by one or more of the following measures:

- Reorient or relocate the receiving antenna.
- Increase the separation between the equipment and receiver.
- Connect the equipment into an outlet on a circuit different from that to which the receiver is connected.
- Consult the dealer or an experienced radio/TV technician for help.

This Class B digital apparatus complies with Canadian ICES-003.

FCC Part 15.19 Warning Statement

THIS DEVICE COMPLIES WITH PART 15 OF THE FCC RULES. OPERATION IS SUBJECT TO THE FOLLOWING TWO CONDITIONS: (1) THIS DEVICE MAY NOT CAUSE HARMFUL INTERFERENCE, AND (2) THIS DEVICE MUST ACCEPT ANY INTERFERENCE RECEIVED, INCLUDING INTERFERENCE THAT MAY CAUSE UNDESIRED OPERATION.

If Canadian approval is requested for devices incorporating PLSx3 modules the below notes will have to be provided in the English and French language in the final user documentation. Manufacturers/OEM Integrators must ensure that the final user documentation does not contain any information on how to install or remove the module from the final product.

5.4 Compliance with FCC and ISED Rules and Regulations

Notes (ISED):

(EN) This Class B digital apparatus complies with Canadian ICES-003 and RSS-210. Operation is subject to the following two conditions: (1) this device may not cause interference, and (2) this device must accept any interference, including interference that may cause undesired operation of the device.

(FR) Cet appareil numérique de classe B est conforme aux normes canadiennes ICES-003 et RSS-210. Son fonctionnement est soumis aux deux conditions suivantes: (1) cet appareil ne doit pas causer d'interférence et (2) cet appareil doit accepter toute interférence, notamment les interférences qui peuvent affecter son fonctionnement.

(EN) Radio frequency (RF) Exposure Information

The radiated output power of the Wireless Device is below the Innovation, Science and Economic Development Canada (ISED) radio frequency exposure limits. The Wireless Device should be used in such a manner such that the potential for human contact during normal operation is minimized.

This device has also been evaluated and shown compliant with the ISED RF Exposure limits under mobile exposure conditions. (antennas at least 20cm from a person's body).

(FR) Informations concernant l'exposition aux fréquences radio (RF)

La puissance de sortie émise par l'appareil de sans fil est inférieure à la limite d'exposition aux fréquences radio d'Innovation, Sciences et Développement économique Canada (ISDE). Utilisez l'appareil de sans fil de façon à minimiser les contacts humains lors du fonctionnement normal.

Ce périphérique a également été évalué et démontré conforme aux limites d'exposition aux RF d'IC dans des conditions d'exposition à des appareils mobiles (les antennes se situent à moins de 20cm du corps d'une personne).

5.5 Compliance with Japanese Rules and Regulations

The PLSx3 reference application described in Section 5.3 complies with the requirements of the Japanese "Telecommunications Business Law" and "Ordinance Concerning Technical Regulations Conformity Certification of Specified Radio Equipment" as well as with the requirements of the Japanese "Radio Law" and "Ordinance Concerning Technical Conditions Compliance Approval and Certification of the Type for Terminal Equipment".

 The certificate granted in accordance with the "Telecommunications Business Law" has the identifier:

AD204118217 (for -J) AD210086217 (for -W)

 The certificate granted in accordance with the "Radio Law" has the identifier: 217-204182 (for -J) 217-210086 (for -W)

Please refer to Figure 51 for the JATE/TELEC mark with identifiers:



Figure 50: JATE/TELEC mark for -J

:



Figure 51: JATE/TELEC mark for -W

6 Document Information

6.1 Revision History

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.202 New document: "Cinterion® PLSx3 Hardware Interface Description" Version **01.300**

Chapter	What is new
-	Remove digital audio function.
2.1.9.3	Revised completed section on fast shutdown.
3.2.1	Revised Figure 26 for ON startup timing.
3.2.2.2	Revised Figure 27 for EMERG_RST timing.
7.1	Updated part number for the new variants.
7.2	Updated label information

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.201 01.202

New document: "Cinterion® PLSx3 Hardware Interface Description" Version 01.202

Chapter	What is new
3.6	Updated Table 20 Electrostatic values.
3.2.2.2	Revised the caution.
4.2.3.1	Revised reflow temperature rating.

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.005t 01.006

New document: "Cinterion® PLSx3 Hardware Interface Description" Version 01.201_01.202

Chapter	What is new
-	Updated for Antenna switch feature.
2.1.2	Updated Table 3 for CCRST.
2.1.5	Updated ASC1 description.
3.2.2.2	Added a caution.
4.2.3.1	Updated reflow temperature rating.
5.1	Added UKCA standard.
7.1	Updated ordering number.
7.2	Updated label information.

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.002d 01.002dNew document: "Cinterion® PLSx3 Hardware Interface Description" Version 01.005_01.006

Chapter	What is new
1.2 2.3	Added QZSS in GNSS.
2.1.9.5	Added this chapter.
2.2.3.1	Added and updated links and updated Figure 19.
2.2.3.2	Updated Figure 21.
7.1	Updated ordering number.
7.2	Updated label information.

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.002c New document: "Cinterion® PLSx3 Hardware Interface Description" Version 01.002d

Chapter	What is new
2.1.2	Updated CCIN to CCIN1 and CCIN2.
2.1.5 2.1.7	Updated Figure 8 and Figure 14
2.4	Updated Figure 25.
3.4	Updated Figure 32.
4.2	Added a note
5.4	Added LET Band8 in Table 33.
7.1	Updated ordering numbers.

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.002b New document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.002c

Chapter	What is new
2.4	Updated Figure 25.

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.002a New document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.002b

Chapter	What is new		
2.1.2	Deleted GPO interface Table 3.		
2.1.4	Added Figure 6.		
2.1.5	Added Figure 7.		
2.1.7	dded Figure 14.		
2.1.8.1	Updated Figure 15.		
2.2.1	Updated Table 9 and Table 12.		
2.3.2	Updated Figure 24.		
2.4	Updated Figure 25 for Sample Application.		
3.4	Added Table 16, Table 17 and Table 18		
3.7	Added new chapter Reliability Characteristics.		
-	Remove I ² C		

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.002 New document: "Cinterion® PLSx3- Hardware Interface Description" Version 01.002a

Chapter	What is new			
1.2.1	Added a note to Table 1.			
2.2	Updated Table 12.			
2.2.3.2	Updated Figure 22.			
2.1.2 3.2.2.2	Updated the low level impulse.			
3.2.3	Updated Table 13 and added a note.			
5.1	Added 1907/2006/EC (REACH) in Table 25.			
5.1.1	New chapter regarding IEC 62368-1 Classification			
5.2	Updated SAR requirement.			
5.4	Added Table 33 and Table .			
7.2	Updated Figure 52.			

Proceeding document "Cinterion® PLSx3- Hardware Interface Description" Version 00.906a New document "Cinterion® PLSx3- Hardware Interface Description" Version 01.002

Chapter	What is new			
1.1	Updated the supported product in the list.			
1.2.1	dded new products and the supported bands in Table 1.			
3.4.2	dded this section.			
3.4.1	Jpdated Table 17 and Table 18.			
3.3.4	Added this section.			
3.2.1	Updated Figure 26.			
5.1.1	New chapter regarding IEC 62368-1 Classification			
7	Added the supported products in Table 35.			

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.024 New document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.906

Chapter	What is new			
2.1.3.1	Add Reducing Power Consumption section.			
2.1.8	Added Analog-to-Digital Converter (ADC) section.			
2.1.9.3, 2.1.9.4	Added Fast shutdown and Remove Wakeup sections.			
3.1	Added Operation Mode section.			
3.2.5	Added Automatic shutdown with sub sections.			
3.3	Added Power Saving section.			
3.6	Added Electrostatic Discharge section.			
4.3.1.2	Added Figure 44.			
4.3.2.2	Added Figure 48 and Table 24.			
5	Added chapter 6 Regulatory and Type Approval Information.			
7.2	Added Module Label Information section.			
3.2.1	Updated Figure 26 and the description of IGT signal.			
2.1.2	Updated Ignition signal description in Table 3.			

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.012 New document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.024

Chapter	What is new		
	Added new variants of -X, -EP, -LA and -J as well as their supported bands.		
	Update the height of the module.		
2.1.1	Updated the pad assignment. Update the number of GPIO to 22.		
2.1.6	Updated Figure 10.		
2	Added the following chapters: 2.1.9.1, 2.2, 2.3, 2.4.		
3.2.5	Added Automatic Shutdown section.		
3.4.1	Updated power consumption.		
3.5	Added Operating Temperatures section.		
	Removed TX-activity.		

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.002 New document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.012

Chapter	What is new	
2	Added the following new sections: 2.1.7, 2.1.8.1, 2.1.9, 2.1.6.1	
3	dded the following new sections: 3.2.2, 3.2.4	
4	Added the following new sections: 4.2.4, 4.3	
2.1.1	Updated the pad assignment	
1.3	Updated Figure 1	
-	Updated company name and logo.	

Proceeding document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.001 New document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.002

Chapter	What is new	
1.4	Jpdated the Figure 2.	
2.1	Added the following new sections: 2.1.3, 2.1.4 2.1.5, 2.1.6	
3	Added section 3.2	

New document: "Cinterion® PLSx3- Hardware Interface Description" Version 00.001

Chapter	What is new
	Initial document setup.

6.2 Related Documents

- [1] PLSx3 AT Command Set
- [2] PLSx3 Release Note
- [3] Universal Serial Bus Specification Revision 2.0, April 27, 2000
- [4] Application Note 48: SMT Module Integration
- [5] Application Note 40:Thermal Solution for Cinterion® PLSx3 Application
- [6] Differences between Selected Cinterion® Modules, Hardware Migration Guide

6.3 Terms and Abbreviations

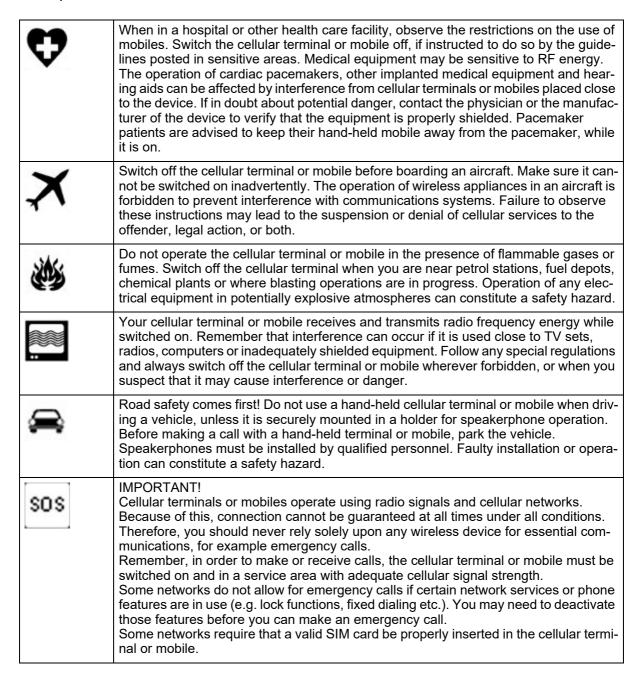
Abbreviation	Description			
ADC	Analog-to-digital converter			
AGC	Automatic Gain Control			
ANSI	American National Standards Institute			
ARFCN	Absolute Radio Frequency Channel Number			
ARP	Antenna Reference Point			
ASC0/ASC1	Asynchronous Controller. Abbreviations used for first and second serial interface of PLSx3			
В	Thermistor Constant			
BER	Bit Error Rate			
BIP	Bearer Independent Protocol			
BTS	Base Transceiver Station			
CB or CBM	Cell Broadcast Message			
CE	Conformité Européene (European Conformity)			
CHAP	Challenge Handshake Authentication Protocol			
CPU	Central Processing Unit			
CS	Coding Scheme			
CSD	Circuit Switched Data			
CTS	Clear to Send			
DAC	Digital-to-Analog Converter			
dBm0	Digital level, 3.14dBm0 corresponds to full scale, see ITU G.711, A-law			
DCE	Data Communication Equipment (typically modems, e.g. Thales module)			
DRX	Discontinuous Reception			
DSB	Development Support Box			
DSP	Digital Signal Processor			
DSR	Data Set Ready			
DTR	Data Terminal Ready			
DTX	Discontinuous Transmission			
EFR	Enhanced Full Rate			

EIRP Equivalent Isotropic Radiated Power EMC Electromagnetic Compatibility ERP Effective Radiated Power ESD Electrostatic Discharge ETS European Telecommunication Standard ETSI European Telecommunication Standards Institute FCC Federal Communications Commission (U.S.) FDMA Frequency Division Multiple Access FR Full Rate GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HIZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-lon Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer PA Power Amplifier	Abbreviation	Description			
ERP Effective Radiated Power ESD Electrostatic Discharge ETS European Telecommunication Standard ETSI European Telecommunication Standards Institute FCC Federal Communications Commission (U.S.) FDMA Frequency Division Multiple Access FR Full Rate GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	EIRP	Equivalent Isotropic Radiated Power			
ESD Electrostatic Discharge ETS European Telecommunication Standard ETSI European Telecommunication Standards Institute FCC Federal Communications Commission (U.S.) FDMA Frequency Division Multiple Access FR Full Rate GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	EMC				
ETS European Telecommunication Standard ETSI European Telecommunication Standards Institute FCC Federal Communications Commission (U.S.) FDMA Frequency Division Multiple Access FR Full Rate GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	ERP				
ETSI European Telecommunication Standards Institute FCC Federal Communications Commission (U.S.) FDMA Frequency Division Multiple Access FR Full Rate GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-lon Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	ESD	Electrostatic Discharge			
FCC Federal Communications Commission (U.S.) FDMA Frequency Division Multiple Access FR Full Rate GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-lon Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	ETS	European Telecommunication Standard			
FDMA Frequency Division Multiple Access FR Full Rate GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	ETSI	European Telecommunication Standards Institute			
FR Full Rate GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	FCC	Federal Communications Commission (U.S.)			
GMSK Gaussian Minimum Shift Keying GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-lon Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	FDMA	Frequency Division Multiple Access			
GPIO General Purpose Input/Output HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	FR	Full Rate			
HiZ High Impedance HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	GMSK	Gaussian Minimum Shift Keying			
HR Half Rate I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	GPIO	General Purpose Input/Output			
I/O Input/Output IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union Kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	HiZ	High Impedance			
IC Integrated Circuit IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	HR	Half Rate			
IMEI International Mobile Equipment Identity ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	I/O	Input/Output			
ISO International Standards Organization ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-Ion/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	IC	Integrated Circuit			
ITU International Telecommunications Union kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	IMEI	International Mobile Equipment Identity			
kbps kbits per second LED Light Emitting Diode Li-lon/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	ISO	International Standards Organization			
LED Light Emitting Diode Li-lon/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	ITU	International Telecommunications Union			
Li-lon/Li+ Lithium-Ion Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	kbps	kbits per second			
Li battery Rechargeable Lithium Ion or Lithium Polymer battery LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	LED	Light Emitting Diode			
LPM Link Power Management Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	Li-lon/Li+	Lithium-lon			
Mbps Mbits per second MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	Li battery	Rechargeable Lithium Ion or Lithium Polymer battery			
MMI Man Machine Interface MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	LPM	Link Power Management			
MO Mobile Originated MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	Mbps	Mbits per second			
MS Mobile Station (module), also referred to as TE MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	MMI	Man Machine Interface			
MSISDN Mobile Station International ISDN number MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	МО	Mobile Originated			
MT Mobile Terminated NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	MS	Mobile Station (module), also referred to as TE			
NTC Negative Temperature Coefficient OEM Original Equipment Manufacturer	MSISDN	Mobile Station International ISDN number			
OEM Original Equipment Manufacturer	MT	Mobile Terminated			
	NTC	Negative Temperature Coefficient			
PA Power Amplifier	OEM	Original Equipment Manufacturer			
	PA	Power Amplifier			
PAP Password Authentication Protocol	PAP	Password Authentication Protocol			
PBCCH Packet Switched Broadcast Control Channel	PBCCH	Packet Switched Broadcast Control Channel			
PCB Printed Circuit Board	PCB	Printed Circuit Board			
PCL Power Control Level	PCL	Power Control Level			
PDU Protocol Data Unit	PDU	Protocol Data Unit			

Abbreviation	Description			
PLL	Phase Locked Loop			
PPP	Point-to-point protocol			
PSK	Phase Shift Keying			
PSU	Power Supply Unit			
PWM	Pulse Width Modulation			
R&TTE	Radio and Telecommunication Terminal Equipment			
RAM	Random Access Memory			
RF	Radio Frequency			
RFFE	RF front-end			
RLS	Radio Link Stability			
RMS	Root Mean Square (value)			
RoHS	Restriction of the use of certain hazardous substances in electrical and electronic equipment.			
ROM	Read-only Memory			
RTC	Real Time Clock			
RTS	Request to Send			
Rx	Receive Direction			
SAR	Specific Absorption Rate			
SAW	Surface Accoustic Wave			
SD	Secure Digital			
SDC	Secure Digital Controller			
SGMII	Serial Gigabit Media Independent Interface			
SELV	Safety Extra Low Voltage			
SIM	Subscriber Identification Module			
SMD	Surface Mount Device			
SMS	Short Message Service			
SMT	Surface Mount Technology			
SPI	Serial Peripheral Interface			
SRAM	Static Random Access Memory			
TA	Terminal adapter (e.g. module)			
TDMA	Time Division Multiple Access			
TE	Terminal Equipment, also referred to as DTE			
TLS	Transport Layer Security			
Тх	Transmit Direction			
UART	Universal asynchronous receiver-transmitter			
URC	Unsolicited Result Code			
USSD	Unstructured Supplementary Service Data			
VSWR	Voltage Standing Wave Ratio			

6.4 Safety Precaution Notes

The following safety precautions must be observed during all phases of the operation, usage, service or repair of any cellular terminal or mobile incorporating PLSx3. Manufacturers of the cellular terminal are advised to convey the following safety information to users and operating personnel and to incorporate these guidelines into all manuals supplied with the product. Failure to comply with these precautions violates safety standards of design, manufacture and intended use of the product. Thales assumes no liability for customer's failure to comply with these precautions.



7 Appendix

7.1 List of Parts and Accessories

Table 35: List of parts and accessories

Description	Supplier	Ordering information
PLS63-X-B	Thales	Standard module Thales IMEI: Packaging unit (ordering) number: L30960-N6500-A130 Module label number: S30960-S6500-A130-11
PLS83-X-B	Thales	Standard module Thales IMEI: Packaging unit (ordering) number: L30960-N6510-A130 Module label number: S30960-S6510-A130-1
PLS63-W-B	Thales	Standard module Thales IMEI: Packaging unit (ordering) number: L30960-N6520-A130 Module label number: S30960-S6520-A130-1
PLS83-W-B	Thales	Standard module Thales IMEI: Packaging unit (ordering) number: L30960-N6530-A130 Module label number: S30960-S6530-A130-1
DSB-mini	Thales	Ordering number: L30960-N0030-A100
DSB75 Evaluation Kit	Thales	Ordering number: L36880-N8811-A100
EVAL DSB Adapter for mounting PLSx3 evaluation modules onto DSB75	Thales	Ordering number: L30960-N0100-A100
LGA DevKit	Thales	LGA DevKit consists of Cinterion® LGA DevKit L Base PCB: Ordering number: L30960-N0112-A100 Cinterion® LGA DevKit Socket SML: Ordering number: L30960-N0110-A100

Table 36: Molex sales contacts (subject to change)

Molex For further information please click: http://www.molex.com	Molex Deutschland GmbH Otto-Hahn-Str. 1b 69190 Walldorf Germany Phone: +49-6227-3091-0 Fax: +49-6227-3091-8100 Email: mxgermany@molex.com	American Headquarters Lisle, Illinois 60532 U.S.A. Phone: +1-800-78MOLEX Fax: +1-630-969-1352
Molex China Distributors Beijing, Room 1311, Tower B, COFCO Plaza No. 8, Jian Guo Men Nei Street, 100005 Beijing P.R. China Phone: +86-10-6526-9628 Fax: +86-10-6526-9730	Molex Singapore Pte. Ltd. 110, International Road Jurong Town, Singapore 629174 Phone: +65-6-268-6868 Fax: +65-6-265-6044	Molex Japan Co. Ltd. 1-5-4 Fukami-Higashi, Yamato-City, Kanagawa, 242-8585 Japan Phone: +81-46-265-2325 Fax: +81-46-265-2365

7.2 Module Label Information

The label engraved on the top of PLSx3 comprises the following information.

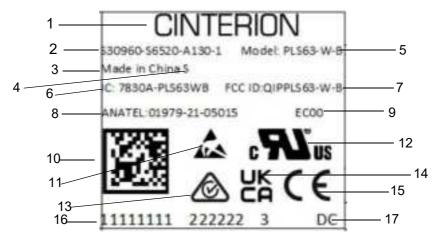


Figure 52: PLSx3 Label

Table 37: PLSx3 label information

No.	
1	Cinterion logo
2	Product order code
3	Manufacturing country (e.g., "Made in China")
4	Factory Code
5	Product name/variant (e.g. "PLS63-W")
6	IC identifier
7	FC identifier
8	ANATEL identifier
9	EC code to indicate the hardware version.
10	Manufacturer 2D barcode
11	Electrostatic discharge (ESD) warning symbol
12	The Underwriter Laboratories (UL) Recognized sign for USA and Canada
13	The Regulatory Compliance Marking (RCM) for Australia
14	United Kingdom Conformity Assessed (UKCA) mark
15	CE conformity mark
16	Product IMEI
17	2-digital date code of product production (for decoding see Table below)

Table 38: Date code table

Date Code												
Code	L	М	N	Р	R	S	Т	U	V	W	Х	Α
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	1	2	3	4	5	6	7	8	9	0	N	D
Month	Jan.	Feb.	Mar.	Apr.	May	June	July	Aug.	Sept.	Oct.	Nov.	Dec.

